







THS4031, THS4032 SLOS224J - JULY 1999 - REVISED FEBRUARY 2024

THS403x 100MHz Low-Noise High-Speed Amplifiers

1 Features

- Ultra-low 1.2nV/√ Hz voltage noise
- High Speed:
 - 100MHz bandwidth [G = 2 (-1), -3dB]
 - 100V/µs slew rate
- Very low distortion
 - THD = -81dBc (f = 1MHz, R_L = 150 Ω)
 - THD = -96dBc (f = 1MHz, R_I = 1k Ω)
- Low 0.3mV (typical) input offset voltage
- 200mA output current drive (typical)
- Typical operation from ±4.5V to ±16V
- Offset nulling pins on the THS4031

2 Applications

- Low-noise, wide-band amplifier for industrial applications
- Voltage-controlled oscillators
- Active filters
- Video amplifiers
- Cable drivers
- **Ultrasound Scanners**
- Vector signal transceiver (VST)
- Data acquisition (DAQ)

1000Ω ADS8422 COG

High-performance, Low-noise Driver for 16-Bit **SAR ADCs**

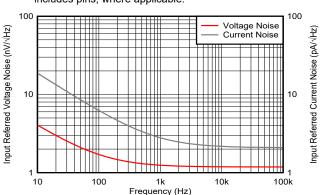
3 Description

The THS4031 and THS4032 (THS403x) are ultra-low voltage noise, high-speed voltage feedback amplifiers that are an excellent choice for applications requiring low voltage noise, including communications and imaging. The single-amplifier THS4031 and the dualamplifier THS4032 offer very good AC performance with 100MHz bandwidth (G = 2), 100V/µs slew rate, and 70ns settling time (0.1%). The THS403x are unity-gain stable with 120MHz bandwidth. These amplifiers have a high drive capability of 200mA and draw only 7.5mA supply current per channel. With -96dBc of total harmonic distortion (THD) at f = 1MHz and a very low noise of 1.2nV/√ Hz, the THS403x are designed for applications requiring low distortion and low noise such as buffering analog-to-digital converters.

Package Information

| · working · · · · · · · · · · · · · · · · · · · | | | | | | |
|---|-----|------------------------|--------------------------------|--|--|--|
| PART NUMBER AMPLIFIERS | | PACKAGE ⁽¹⁾ | PACKAGE SIZE ⁽²⁾ | | | |
| THS4031 | One | D (SOIC, 8) | 4.9mm × 6mm | | | |
| | | DGN (HVSSOP, 8) | 3.0mm × 4.9mm | | | |
| THS4032 | Two | D (SOIC, 8) | 4.9mm × 6mm | | | |
| THS4032 | TWO | DGN (HVSSOP, 8) | 3.0mm × 4.9mm | | | |

- For more information, see Section 10. (1)
- (2)The package size (length × width) is a nominal value and includes pins, where applicable.



Voltage and Current Noise vs Frequency



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4 Pin Configuration and Functions

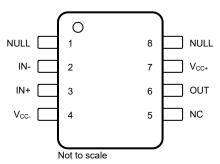


Figure 4-1. THS4031: D Package, 8-Pin SOIC, or DGN Package, 8-pin HVSSOP (Top View)

Table 4-1. Pin Functions: THS4031

| PIN | | TYPE | DESCRIPTION |
|-------------------|------|--------|-----------------------|
| NAME | NO. | ITPE | DESCRIPTION |
| IN- | 2 | Input | Inverting input |
| IN+ | 3 | Input | Non-inverting input |
| NC | 5 | _ | No connection |
| NULL | 1, 8 | Input | Voltage offset adjust |
| OUT | 6 | Output | Output of amplifier |
| V _{CC} - | 4 | _ | Negative power supply |
| V _{CC+} | 7 | _ | Positive power supply |

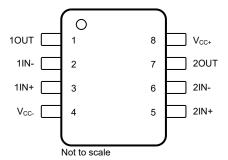


Figure 4-2. THS4032: D Package, 8-Pin SOIC, or DGN Package, 8-pin HVSSOP (Top View)

Table 4-2. Pin Functions: THS4032

| | DINI | | |
|--|------|--------|-------------------------------|
| The state of the s | PIN | TYPE | DESCRIPTION |
| NAME | NO. | | DECORAL HON |
| 1IN- | 2 | Input | Channel 1 inverting input |
| 1IN+ | 3 | Input | Channel 1 non-inverting input |
| 10UT | 1 | Output | Channel 1 output |
| 2IN- | 6 | Input | Channel 2 inverting input |
| 2IN+ | 5 | Input | Channel 2 non-inverting input |
| 2OUT | 7 | Output | Channel 2 output |
| V _{CC} - | 4 | _ | Negative power supply |
| V _{CC+} | 8 | _ | Positive power supply |



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

| | 3 1 3 (| , | MIN | MAX | UNIT |
|---|--|--|-----|------------------|------|
| V _{CC} - to V _{CC} + | Supply voltage | | | 33 | V |
| VI | Input Voltage | | | ±V _{CC} | |
| Io | Output current ⁽²⁾ | | | 240 | mA |
| V _{IO} | Differential input voltage | | | ±1.5 | V |
| I _{IN} | Continuous input current | | | 10 | mA |
| _ | Operating free air temperature | C-suffix | 0 | 70 | °C |
| I _A | Operating free-air temperature | I-suffix | -40 | 85 | |
| | | Any condition | | 150 | °C |
| T _J | Junction temperature | Maximum junction temperature, continuous operation, long term reliability ⁽³⁾ | | 130 | °C |
| | Lead temperature 1,6 mm (1/16 inch) fr | Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds | | 300 | °C |
| | Storage temperature T _{stg} | | -65 | 150 | °C |

⁽¹⁾ Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

5.2 ESD Ratings

| | | | VALUE | UNIT |
|---------------------------|---|---|-------|------|
| V Floatroatatic disabores | Human body model (HBM), per ANSI/ESDA/ JEDEC JS-001, all pins ⁽¹⁾ | ±1000 | \/ | |
| V _(ESD) | Electrostatic discharge | Charged device model (CDM), per JEDEC specification JS-002 ⁽²⁾ | ±1000 | V |

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | NOM | MAX | UNIT |
|--------------------------|--------------------------------|---------------|------|-----|-----|-------|
| V _{CC} Suppl | Supply voltage | Dual-supply | ±4.5 | ±15 | ±16 | V |
| | Supply voltage | Single-supply | 9 | 30 | 32 | |
| T _A Operating | Operating free air temperature | C-suffix | 0 | 25 | 70 | °C |
| | Operating free-air temperature | I-suffix | -40 | 25 | 85 | 1 6 1 |

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⁽²⁾ When continuously operating at any output current, do not exceed the maximum junction temperature. Keep the output current less than the absolute maximum rating regardless of time interval.

⁽³⁾ The maximum junction temperature for continuous operation is limited by package constraints. Operation greater than this temperature can result in reduced reliability, lifetime of the device, or both.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



5.4 Thermal Information: THS4031

| | | THS | THS4031 | | |
|-----------------------|--|----------|--------------|------|--|
| | THERMAL METRIC ⁽¹⁾ | D (SOIC) | DGN (HVSSOP) | UNIT | |
| | | 8 PINS | 8 PINS | | |
| R _{0JA} | Junction-to-ambient thermal resistance | 124.5 | 60.7 | °C/W | |
| R _{0JC(top)} | Junction-to-case (top) thermal resistance | 65.0 | 87.4 | °C/W | |
| R _{θJB} | Junction-to-board thermal resistance | 72.2 | 33 | °C/W | |
| Ψ_{JT} | Junction-to-top characterization parameter | 13.6 | 7.9 | °C/W | |
| Ψ_{JB} | Junction-to-board characterization parameter | 71.3 | 32.9 | °C/W | |
| R _{0JC(bot)} | Junction-to-case (bottom) thermal resistance | N/A | 17.2 | °C/W | |

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5.5 Thermal Information: THS4032

| | | TH | THS4032 | | |
|-----------------------|--|----------|--------------|------|--|
| | THERMAL METRIC ⁽¹⁾ | D (SOIC) | DGN (HVSSOP) | UNIT | |
| | | 8 PINS | 8 PINS | | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance | 121.2 | 56.5 | °C/W | |
| R _{0JC(top)} | Junction-to-case (top) thermal resistance | 72.8 | 48.4 | °C/W | |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 61.4 | 37.7 | °C/W | |
| Ψ_{JT} | Junction-to-top characterization parameter | 18.2 | 2.5 | °C/W | |
| Ψ_{JB} | Junction-to-board characterization parameter | 61 | 37.5 | °C/W | |
| R _{0JC(bot)} | Junction-to-case (bottom) thermal resistance | N/A | 9.9 | °C/W | |

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.



5.6 Electrical Characteristics: THS4031, R_L = **150** Ω at T_A = 25°C, V_{CC} = ±15 V, and R_L = 150 Ω (unless otherwise noted)

| | PARAMETER | TEST CONI | DITIONS | MIN TYP | MAX | UNIT |
|-----------------|-----------------------------------|--|---|-------------|-----|--------|
| DYNAMIC | PERFORMANCE | | | | | |
| | Small-signal bandwidth (–3 dB) | Gain = -1 or 2 | V _{CC} = ±15 V | 100 | | MHz |
| BW | | | V _{CC} = ±5 V | 90 | | |
| | Dandwidth for 0.4 dD flatness | Coin = 1 or 2 | V _{CC} = ±15 V | 9 | | MU |
| | Bandwidth for 0.1-dB flatness | Gain = -1 or 2 | V _{CC} = ±5 V | 9 | | MHz |
| SR | Slew rate ⁽¹⁾ | Gain = -1 | V _{CC} = ±15 V, 20-V step | 100 | | V/µs |
| | | | VCC = ±5 V, 5-V step | 80 | | |
| | Settling time to 0.1% | Gain = –1 | V _{CC} = ±15 V, 5-V step | 70 | | ns |
| t- | Settling time to 0.176 | Gaiii i | V _{CC} = ±5 V, 2.5-V step | 55 | | 115 |
| t _S | Settling time to 0.01% | Gain = –1 | V _{CC} = ±15 V, 5-V step | 90 | | ns |
| | Settling time to 0.01 % | Gaiii i | V _{CC} = ±5 V, 2.5-V step | 80 | | 115 |
| | | | $V_{CC} = \pm 15 \text{ V}, V_{O} = 3 \text{ V}_{RMS}$ | -137 | | dB |
| | | Gain = 1, $R_L = 600 \Omega$, $f = 1 \text{ kHz}$, | VCC - 113 V, VO-3 VRMS | 0.000014 | | % |
| | | BW = 80 kHz | $V_{CC} = \pm 5 \text{ V}, V_{O} = 1 \text{ V}_{RMS}$ | -130 | | dB |
| THD+N | T | | V _{CC} - ±3 V, V _O -1 V _{RMS} | 0.00003 | | % |
| ו חט+וא | Total harmonic distortion + noise | | V _{CC} = ±15 V, V _O =3 V _{RMS} | -133 | | dB |
| | | Gain = 2, R_L = 600 Ω , f = 1 kHz, | V _{CC} = ±15 V, V _O =3 V _{RMS} | 0.000022 | | % |
| | | BW = 80 kHz | $V_{CC} = \pm 5 \text{ V}, V_{O} = 1 \text{ V}_{RMS}$ | -124 | | dB |
| | | | V _{CC} = ±5 V, V _O =1 V _{RMS} | 0.00006 | | % |
| | Intermodulation distortion | G = 1, R _L = 600 Ω , SMPTE/DIN two-tone, 4:1 (60 Hz and 7 kHz) | V = 145 V V = 2 V | -130 | | dB |
| | | | $V_{CC} = \pm 15 \text{ V}, V_{O} = 3 \text{ V}_{RMS}$ | 0.000032 | | % |
| | | | V - 15 V V -4 V | -126 | | dB |
| | | | $V_{CC} = \pm 5 \text{ V}, V_{O} = 1 \text{ V}_{RMS}$ | 0.00005 | | % |
| IMD | | G = 2, R _L = 600 Ω , SMPTE/DIN two-tone, 4:1 (60 Hz and 7 kHz) | V = 145 V V = 2 V | -126 | | dB |
| | | | $V_{CC} = \pm 15 \text{ V}, V_{O} = 3 \text{ V}_{RMS}$ | 0.00005 | | % |
| | | | V - 15 V V -4 V | -120 | | dB |
| | | | $V_{CC} = \pm 5 \text{ V}, V_{O} = 1 \text{ V}_{RMS}$ | 0.0001 | | % |
| NOISE/DI | ISTORTION PERFORMANCE | • | | | | |
| THD | Total Harmonic Distortion | G =2, V _{CC} = ±5 V or ±15 V, f = 1 N | 1Hz V _{O(pp)} = 2 V | – 81 | | dBc |
| V _n | Input voltage noise | V _{CC} = ±5 V or ±15 V, f > 10 kHz | | 1.2 | | nV/√Hz |
| In | Input current noise | V _{CC} = ±5 V or ±15 V, f > 10 kHz | | 2.3 | | pA/√Hz |
| | Differential ratio | | V _{CC} = ±15 V | 0.015% | | |
| | Differential gain error | G = 2, 40 IRE modulation, NTSC | V _{CC} = ±5 V | 0.02% | | |
| | D:# 1: 1 1 | and PAL, ±100 IRE ramp | V _{CC} = ±15 V | 0.025 | | ۰ |
| | Differential phase error | | V _{CC} = ±5 V | 0.03 | • | |
| DC PERF | ORMANCE | | | | | |
| | | V .45VV .40V | T _A = 25°C | 93 100 | | dB |
| | | $V_{CC} = \pm 15 \text{ V}, V_{O} = \pm 10 \text{ V}$ | T _A = full range | 92 | | dB |
| | Open loop gain | | T _A = 25°C | 90 98 | | dB |
| | | $V_{CC} = \pm 5 \text{ V}, V_{O} = \pm 2.5 \text{ V}$ | T _A = full range | 89 | | dB |
| ., | | V .5V5V | T _A = 25°C | 0.3 | 2 | ., |
| V _{OS} | Input offset voltage | $V_{CC} = \pm 5 \text{ V or } \pm 15 \text{ V}$ | T _A = full range | | 3 | mV |
| | Offset voltage drift | V _{CC} = ±5 V or ±15 V | T _A = full range | 2 | | μV/°C |
| | | | T _A = 25°C | 9 | 20 | |
| I _{IB} | Input bias current | $V_{CC} = \pm 5 \text{ V or } \pm 15 \text{ V}$ | T _A = full range | | 33 | μA |
| | | | T _A = 25°C | 30 | 250 | |
| los | Input offset current | V _{CC} = ±5 V or ±15 V | T _A = full range | | 400 | nA |

at T_A = 25°C, V_{CC} = ± 15 V, and R_L = 150 Ω (unless otherwise noted)

| | PARAMETER | TEST CO | ONDITIONS | MIN | TYP | MAX | UNIT |
|-----------|-------------------------------|---|-----------------------------|-------|-------|-----|-------|
| | Input offset current | V _{CC} = ±5 V or ±15 V | T _A = full range | | 0.2 | | nA/°C |
| INPUT C | HARACTERISTICS | | | | | | |
| V | Common-mode input voltage | V _{CC} = ±15 V | | ±13.5 | ±14.3 | | V |
| V_{ICR} | range | V _{CC} = ±5 V | | ±3.8 | ±4.3 | | V |
| | | V - 145 V V - 140 V | T _A = 25°C | 85 | 95 | | |
| CMRR | Common made valention ratio | $V_{CC} = \pm 15 \text{ V}, V_{ICR} = \pm 12 \text{ V}$ | T _A = full range | 80 | | | |
| CIVIRR | Common-mode rejection ratio | V _{CC} = ±5 V, V _{ICR} = ±2.5 V | T _A = 25°C | 90 | 100 | | dB |
| | | | T _A = full range | 85 | | | |
| ri | Input resistance | | | | 2 | | ΜΩ |
| Ci | Input capacitance | | | | 1.5 | | pF |
| OUTPUT | CHARACTERISTICS | | | | | | |
| V | Output valtage eving | V _{CC} = ±15 V | R _L = 250 Ω | ±12 | ±12.9 | | V |
| Vo | Output voltage swing | V _{CC} = ±5 V | | ±3 | ±3.5 | | V |
| | Output ourront(2) | D = 10.0 | V _{CC} = ±15 V | 60 | 200 | | mA |
| lo | Output current ⁽²⁾ | $R_L = 10 \Omega$ | V _{CC} = ±5 V | 50 | 160 | | mA |
| Ro | Output resistance | Open loop | | | 5 | | Ω |

at T_A = 25°C, V_{CC} = ±15 V, and R_L = 150 Ω (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|-----------------|---------------------------------|---------------------------------|-----------------------------|------|-----|----------|------|
| POWER | SUPPLY | | | • | | <u>'</u> | |
| V | Supply voltage energting range | Dual supply | | ±4.5 | | ±16.5 | V |
| V _{CC} | Supply voltage operating range | Single supply | | 9 | | 33 | V |
| | | V _{CC} = ±15 V | T _A = 25°C | | 7.5 | 10 | mA |
| | Supply current (each amplifier) | | T _A = full range | | | 11 | |
| Icc | Supply current (each ampliner) | V + 5 V | T _A = 25°C | | 6.5 | 9 | IIIA |
| | | $V_{CC} = \pm 5 V$ | T _A = full range | | | 10.5 | |
| PSRR | Dower aupply rejection ratio | V _{CC} = ±5 V or ±15 V | T _A = 25°C | 85 | 95 | | dB |
| PSRR | Power-supply rejection ratio | | T _A = full range | 80 | | | ub |

- (1) Slew rate is measured from an output level range of 25% to 75%.
- (2) Keep junction temperature less than the absolute maximum rating when the output is heavily loaded or shorted; see also Section 5.1

5.7 Electrical Characteristics: THS4031, R_L = 1 $k\Omega$

at T_A = full range, V_{CC} = ±15 V, and R_L = 1 k Ω (unless otherwise noted)

| gain bandwidth -signal bandwidth 3) width for 0.1-dB flatness ower bandwidth ⁽²⁾ rate ag time to 0.1% | $V_{CC} = \pm 15 \text{ V, closed loop}$ $Gain = -1 \text{ or } 2$ $Gain = -1 \text{ or } 2$ $V_{CC} = \pm 15 \text{ V, } V_{O(pp)} = 20 \text{ V}$ $V_{CC} = \pm 5 \text{ V, } V_{O(pp)} = 5 \text{ V}$ $Gain = -1$ | $V_{CC} = \pm 15 \text{ V}$ $V_{CC} = \pm 5 \text{ V}$ $V_{CC} = \pm 15 \text{ V}$ $V_{CC} = \pm 15 \text{ V}$ $V_{CC} = \pm 15 \text{ V}$ | 1 5 80(1) 1 | 20 00 90 9 9 9 1.6 5.1 | MHz MHz MHz |
|--|--|---|--|---|--|
| o-signal bandwidth 3) width for 0.1-dB flatness ower bandwidth ⁽²⁾ rate ng time to 0.1% | Gain = -1 or 2 Gain = -1 or 2 $V_{CC} = \pm 15 \text{ V}, V_{O(pp)} = 20 \text{ V}$ $V_{CC} = \pm 5 \text{ V}, V_{O(pp)} = 5 \text{ V}$ | $V_{CC} = \pm 5 \text{ V}$ $V_{CC} = \pm 15 \text{ V}$ $V_{CC} = \pm 5 \text{ V}$ $V_{CC} = \pm 15 \text{ V}$ | 1 1 5 80(1) 1 | 90 9 9 9 9 1.6 5.1 | MHz |
| width for 0.1-dB flatness ower bandwidth ⁽²⁾ rate ng time to 0.1% | Gain = -1 or 2 $V_{CC} = \pm 15 \text{ V}, V_{O(pp)} = 20 \text{ V}$ $V_{CC} = \pm 5 \text{ V}, V_{O(pp)} = 5 \text{ V}$ | $V_{CC} = \pm 5 \text{ V}$ $V_{CC} = \pm 15 \text{ V}$ $V_{CC} = \pm 5 \text{ V}$ $V_{CC} = \pm 15 \text{ V}$ | 80 ⁽¹⁾ 1 | 90 9 9 1.6 5.1 | MHz |
| width for 0.1-dB flatness ower bandwidth ⁽²⁾ rate ng time to 0.1% | Gain = -1 or 2 $V_{CC} = \pm 15 \text{ V}, V_{O(pp)} = 20 \text{ V}$ $V_{CC} = \pm 5 \text{ V}, V_{O(pp)} = 5 \text{ V}$ | $V_{CC} = \pm 15 \text{ V}$ $V_{CC} = \pm 5 \text{ V}$ $V_{CC} = \pm 15 \text{ V}$, 5-V step | 80 ⁽¹⁾ 1 | 9 9 1.6 5.1 | MHz |
| ower bandwidth ⁽²⁾ rate ng time to 0.1% | $V_{CC} = \pm 15 \text{ V}, V_{O(pp)} = 20 \text{ V}$ $V_{CC} = \pm 5 \text{ V}, V_{O(pp)} = 5 \text{ V}$ | V_{CC} = ±5 V V_{CC} = ±15 V, 5-V step | 80 ⁽¹⁾ 1 | 9 1.6 5.1 | |
| ower bandwidth ⁽²⁾ rate ng time to 0.1% | $V_{CC} = \pm 15 \text{ V}, V_{O(pp)} = 20 \text{ V}$ $V_{CC} = \pm 5 \text{ V}, V_{O(pp)} = 5 \text{ V}$ | V _{CC} = ±15 V, 5-V step | 80 ⁽¹⁾ 1 | 5.1 | |
| rate ng time to 0.1% | V _{CC} = ±5 V, V _{O(pp)} = 5 V | | 80 ⁽¹⁾ 1 | 5.1 | MHz |
| rate ng time to 0.1% | | | 80 ⁽¹⁾ 1 | | IVIHZ |
| ng time to 0.1% | Gain = -1 | | | 00 | |
| | Gain = -1 | | | 00 | V/µs |
| | Gain = -1 | | | 70 | |
| ng time to 0.01% | | V _{CC} = ±5 V, 2.5-V step | - | 55 | ns |
| ig time to 0.01% | 0-: 4 | V _{CC} = ±15 V, 5-V step | - | 90 | |
| | Gain = -1 | V _{CC} = ±5 V, 2.5-V step | | 80 | ns |
| | | V - 145 V V -2 V | -1 | 37 | dB |
| | Gain = 1, $R_L = 2 k\Omega$, $f = 1 kHz$, | $V_{CC} = \pm 15 \text{ V}, V_O = 3 \text{ V}_{RMS}$ | 0.0000 | 14 | % |
| Total harmonic distortion + noise | BW = 80 kHz | $V_{CC} = \pm 5 \text{ V}, V_{O} = 1 \text{ V}_{RMS}$ | -1 | 30 | dB |
| | | VCC - 15 V, VO-1 VRMS | 0.000 | 03 | % |
| | | \\. = ±15\\\\\.=2\\. | -1 | 33 | dB |
| | Gain = 2, R_L = 2 k Ω , f = 1 kHz, | VCC - 110 V, VO-3 VRMS | 0.0000 | 22 | % |
| | BW = 80 kHz | $V_{CC} = \pm 15 \text{ V}, V_{O} = 3 \text{ V}_{RMS}$ $V_{CC} = \pm 5 \text{ V}, V_{O} = 1 \text{ V}_{RMS}$ | -1 | 24 | dB |
| | | | 0.000 | 06 | % |
| | | | -1 | 30 | dB |
| | | VCC - 113 V, VO-3 VRMS | 0.0000 | 32 | % |
| | and 7 kHz) | | -1 | 26 | dB |
| andulation distortion | | VCC - 13 V, VO-1 VRMS | 0.000 | 05 | % |
| เอนนเสนปา นเรเบานอก | | Voc = +15 V Vo=3 Vo | -1 | 26 | dB |
| | G =2, R_L = 2 $k\Omega$, SMPTE/DIN | VCC - ±13 V, VO-3 VRMS | 0.000 | 05 | % |
| | two-tone, 4:1 (60 Hz and 7 kHz) | Voc = +5 \/ Vo=1 \/p | -1 | 20 | dB |
| | $V_{CC} = \pm 5 \text{ V}, V_{O} = 1 \text{ V}_{RMS}$ | | 0.00 | 01 | % |
| ION PERFORMANCE | | | | | |
| | $G = 2$, $V_{CC} = \pm 5$ V or ± 15 V, $f = 1$ M | _ | 96 | dBc | |
| ı | armonic distortion | odulation distortion $G = 2, R_L = 2 \text{ k}\Omega, \text{ SMPTE/DIN}$ two-tone, 4:1 (60 Hz and 7 kHz) ON PERFORMANCE armonic distortion $G = 2, V_{CC} = \pm 5 \text{ V or } \pm 15 \text{ V, } f = 1 \text{ N}$ | odulation distortion $G = 1, R_L = 2 \text{ k}\Omega, V_O = 1 \text{ V}_{RMS}, \\ \text{SMPTE/DIN two-tone, 4:1 (60 Hz)} \\ V_{CC} = \pm 5 \text{ V, V}_O = 1 \text{ V}_{RMS} \\ V_{CC} = \pm 5 \text{ V, V}_O = 1 \text{ V}_{RMS} \\ V_{CC} = \pm 15 \text{ V, V}_O = 3 \text{ V}_{RMS} \\ V_{CC} = \pm 5 \text{ V, V}_O = 1 \text{ V}_{RMS} \\ V_{CC} = 1 \text{ V}_{RMS}$ | | $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$ |

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5.7 Electrical Characteristics: THS4031, $R_L = 1 k\Omega$ (continued)

at T_A = full range, V_{CC} = ±15 V, and R_L = 1 k Ω (unless otherwise noted)

| PARAMETER | | TEST C | TEST CONDITIONS | | TYP | MAX | UNIT |
|-----------------|----------------------------|---|-----------------------------|----|-----|-----|-------|
| | | V - 145 V V - 140 V | T _A = 25°C | 93 | 100 | | |
| | Open loop gain | $V_{CC} = \pm 15 \text{ V}, V_{O} = \pm 10 \text{ V}$ | T _A = full range | 92 | | | dB |
| | | V - 15 V V - 12 5 V | T _A = 25°C | 92 | 98 | | uБ |
| | | $V_{CC} = \pm 5 \text{ V}, V_{O} = \pm 2.5 \text{ V}$ | T _A = full range | 91 | | | |
| \/ | lengt offeet veltere | V _{CC} = ±5 V or ±15 V | T _A = 25°C | | 0.3 | 2 | mV |
| Vos | Input offset voltage | | T _A = full range | | | 3 | mV |
| Vos | Offset voltage drift | V _{CC} = ±5 V or ±15 V | T _A = full range | | 2 | | μV/°C |
| | Innut high augrent | V = 15 V or 145 V | T _A = 25°C | | 9 | 20 | |
| I _{IB} | Input bias current | $V_{CC} = \pm 5 \text{ V or } \pm 15 \text{ V}$ | T _A = full range | | | 33 | μA |
| | Innut offset surrent | V = 15 V or 145 V | T _A = 25°C | | 30 | 250 | |
| los | Input offset current | $V_{CC} = \pm 5 \text{ V or } \pm 15 \text{ V}$ | T _A = full range | | | 400 | μA |
| | Input offset current drift | V _{CC} = ±5 V or ±15 V | T _A = full range | | 0.2 | | nA/°C |

5.7 Electrical Characteristics: THS4031, $R_L = 1 k\Omega$ (continued)

at T_A = full range, V_{CC} = ±15 V, and R_I = 1 k Ω (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | | MIN | TYP | MAX | UNIT | |
|------------------|----------------------------------|---|-----------------------------|-----------------------------|-------|----------|------|--|
| INPUT C | HARACTERISTICS | | | <u>'</u> | | <u> </u> | | |
| \/ | Common-mode input voltage | V _{CC} = ±15 V V _{CC} = ±5 V | | ±13.5 | ±14.3 | | V | |
| V _{ICR} | range | | | ±3.8 | ±4.3 | | V | |
| | | V _{CC} = ±15 V, V _{ICR} = ±12 V | T _A = 25°C | 85 | 95 | | | |
| CMRR | Common-mode rejection ratio | VCC - ±13 V, VICR - ±12 V | T _A = full range | 80 | | | dB | |
| CIVIKK | Common-mode rejection ratio | V _{CC} = ±5 V, V _{ICR} = ±2.5 V | T _A = 25°C | 90 | 100 | | uБ | |
| | | | VCC - ±3 V, VICR - ±2.3 V | T _A = full range | 85 | | | |
| rį | Input resistance | | | | 2 | | МΩ | |
| Ci | Input capacitance | | | | 1.5 | | pF | |
| OUTPUT | CHARACTERISTICS | | | • | | | | |
| Vo | Output voltage swing | V _{CC} = ±15 V V _{CC} = ±5 V | | ±13 | ±13.6 | | V | |
| v _O | Output voltage swing | | | ±3.4 | ±3.8 | | v | |
| Ro | Output resistance | Open loop | | | 5 | | Ω | |
| POWER | SUPPLY | | | • | | | | |
| \/ | Cumply valtage energting range | Dual supply | | ±4.5 | | ±16.5 | V | |
| V _{CC} | Supply voltage operating range | Single supply | | 9 | | 33 | V | |
| | | V = 145 V | T _A = 25°C | | 7.5 | 10 | | |
| | Cumply augrent (analy amplifier) | V _{CC} = ±15 V | T _A = full range | | | 11 | Λ | |
| I _{CC} | Supply current (each amplifier) | V - 15 V | T _A = 25°C | | 6.5 | 9 | mA | |
| | | $V_{CC} = \pm 5 \text{ V}$ | T _A = full range | | | 10 | | |
| DODD | Downer ownship rojection reti- | V = 15 V or 145 V | T _A = 25°C | 85 | 95 | | | |
| PSRR | Power-supply rejection ratio | $V_{CC} = \pm 5 \text{ V or } \pm 15 \text{ V}$ | T _A = full range | 80 | | | dB | |

⁽¹⁾ This parameter is not tested.

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⁽²⁾ Full power bandwidth = slew rate / $[\pi V_{O(P-P)}]$.



5.8 Electrical Characteristics: THS4032, R_L = **150** Ω at T_A = 25°C, V_{CC} = ±15 V, and R_I = 150 Ω (unless otherwise noted)

| | PARAMETER | | = 150 Ω (unless otherwise TEST CON | | MIN | TYP | MAX | UNIT |
|------------------|---|---|---|---|-------|--------|-----|--------------------|
| DYNAMI | C PERFORMANCE | | | | | | | |
| | | | | V _{CC} = ±15 V | | 100 | | |
| | Small-signal bandwidt | h (–3 dB) | Gain = -1 or 2 | V _{CC} = ±5 V | | 90 | | MHz |
| 3W | | | | V _{CC} = ±15 V | | 50 | | |
| | Bandwidth for 0.1-dB flatness | | Gain = -1 or 2 | V _{CC} = ±5 V | | 45 | | MHz |
| | | | | V _{CC} = ±15 V, 20-V step | | 100 | | |
| SR | Slew rate ⁽¹⁾ | | Gain = -1 | $V_{CC} = \pm 5 \text{ V, 5-V step}$ | | 80 | | V/µs |
| | | | | $V_{CC} = \pm 15 \text{ V}, 5-\text{V step}$ | | 60 | | |
| | Settling time to 0.1% | | Gain = -1 | V _{CC} = ±5 V, 2.5-V step | | 45 | | ns |
| ts | | | | $V_{CC} = \pm 15 \text{ V}, 5-\text{V step}$ | | 90 | | |
| | Settling time to 0.01% | | Gain = -1 | V _{CC} = ±5 V, 2.5-V step | | 80 | | ns |
| NOISE/D | STORTION PERFORMANCE | | | VCC 10 V, 2.0 V 0.0p | | | | |
| THD | Total Harmonic Distortion | | Gain = 2, V _{CC} = ±5 V or ±15 V, f | ain = 2, V _{CC} = ±5 V or ±15 V, f = 1 MHz V _{O(pp)} = 2 V, | | -72 | | dBc |
| / _n | Input voltage noise | | V _{CC} = ±5 V or ±15 V, f > 10 kHz | c = ±5 V or ±15 V. f > 10 kHz | | 1.6 | | nV/√ Hz |
| n n | Input current noise | | $V_{CC} = \pm 5 \text{ V or } \pm 15 \text{ V, f} > 10 \text{ kHz}$ | | | 1.2 | | pA/√ Hz |
| | | | 00 1 7 | V _{CC} = ±15 V | | 0.015% | | |
| | Differential gain error | | Gain = 2, 40 IRE modulation, NTSC and | V _{CC} = ±5 V | | 0.02% | | |
| | | | PAL, | V _{CC} = ±15 V | | 0.025 | | |
| | Differential phase error | | ±100 IRE ramp | V _{CC} = ±5 V | | 0.03 | | 0 |
| | Channel-to-channel cr (THS4032 only) | osstalk | V _{CC} = ±5 V or ±15 V, f = 1 MHz | | | -61 | | dBc |
| OC PERI | FORMANCE | | | | | | | |
| , | Input offset voltage | | V _{CC} = ±5 V or ±15 V | T _A = 25°C | | 0.5 | 2 | ., |
| / _{OS} | | | | T _A = full range | | | 3 | mV |
| | | | | T _A = 25°C | | 30 | 250 | |
| os | Input offset current | $V_{CC} = \pm 5 \text{ V or } \pm 15 \text{ V}$ | T _A = full range | | | 400 | nA | |
| | Offset voltage drift | | V _{CC} = ±5 V or ±15 V | T _A = full range | | 2 | | μV/°C |
| | Input offset current dri | ft | V _{CC} = ±5 V or ±15 V | T _A = full range | | 0.2 | | nA/°C |
| NPUT C | HARACTERISTICS | | | | | | | |
| , | Common-mode input | /oltage | V _{CC} = ±15 V | | ±13.5 | ±14 | | |
| / _{ICR} | range | J | V _{CC} = ±5 V | | ±3.8 | ±4 | | V |
| | | | V .45.V.V .40.V | T _A = 25°C | 85 | 95 | | |
| OMBD. | | | $V_{CC} = \pm 15 \text{ V}, V_{ICR} = \pm 12 \text{ V}$ | T _A = full range | 80 | | | ID. |
| CMRR | Common-mode rejecti | on ratio | V .5V/V .05V | T _A = 25°C | 90 | 100 | | dB |
| | | | $V_{CC} = \pm 5 \text{ V}, V_{ICR} = \pm 2.5 \text{ V}$ | T _A = full range | 85 | | | |
| i | Input resistance | | | | | 2 | | ΜΩ |
| C _i | Input capacitance | | | | | 1.5 | | pF |
| DUTPUT | CHARACTERISTICS | | | | | | | |
| 1- | Output voltage aving | | V _{CC} = ±15 V | R _L = 250 Ω | ±12 | ±12.9 | | V |
| / ₀ | Output voltage swing | | V _{CC} = ±5 V | | ±3 | ±3.5 | | V |
| | Output 200 | | D = 20 O | V _{CC} = ±15 V | 60 | 90 | | , A |
| 0 | Output current ⁽²⁾ | | $R_L = 20 \Omega$ | V _{CC} = ±5 V | 50 | 70 | | mA |
| I _{sc} | Short-circuit current ⁽²⁾ | | V _{CC} = ±15 V | V _{CC} = ±15 V | | 150 | | mA |
| R _O | Output resistance | | Open loop | Open loop | | 13 | | Ω |



at T_A = 25°C, V_{CC} = ± 15 V, and R_L = 150 Ω (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|-----------------|-----------------------------------|--|-----------------------------|------|-----|-------|------|
| POWER | SUPPLY | | | | | | |
| V | Supply voltage energting range | Dual supply | | ±4.5 | | ±16.5 | V |
| V_{CC} | Supply voltage operating range | Single supply | | 9 | | 33 | V |
| | Supply current (each amplifier) | V _{CC} = ±15 V | T _A = 25°C | | 8.5 | 10 | |
| | | | T _A = full range | | | 11 | mA |
| I _{CC} | | V +5 V | T _A = 25°C | | 7.5 | 9 | IIIA |
| | | $V_{CC} = \pm 5 V$ | T _A = full range | | | 10.5 | |
| Debb | PSRR Power-supply rejection ratio | V = 15 V == 145 V | T _A = 25°C | 85 | 95 | | dB |
| FORK | | Power-supply rejection ratio $V_{CC} = \pm 5 \text{ V or } \pm 15 \text{ V}$ | T _A = full range | 80 | | | uБ |

Slew rate is measured from an output level range of 25% to 75%.

5.9 Electrical Characteristics: THS4032, $R_L = 1 \text{ k}\Omega$ at T_A = full range, V_{CC} = ±15 V, and R_I = 1 k Ω (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|-----------------|-------------------------------------|--|--|-----------------------|-----|-----|--------|
| DYNAM | IC PERFORMANCE | | | • | | | |
| | Unity gain bandwidth | V _{CC} = ±15 V, closed loop | | 100(1) | 120 | | MHz |
| | Small-signal bandwidth | Gain = –1 or 2 | V _{CC} = ±15 V | | 100 | | MHz |
| | (–3 dB) | Gaiii = = 1 Oi 2 | V_{CC} = ±5 V | | 90 | | IVIII |
| BW | Bandwidth for 0.1-dB flatness | Gain = –1 or 2 | V _{CC} = ±15 V | | 50 | | MH |
| | Dandwidth for 0.1-db flatfiess | Guil 1 of 2 | $V_{CC} = \pm 5 V$ | | 45 | | IVII I |
| | Full power bandwidth ⁽²⁾ | $V_{CC} = \pm 15 \text{ V}, V_{O(pp)} = 20 \text{ V}$ | | | 2.3 | | MH |
| | I uli power bandwidin | $V_{CC} = \pm 5 \text{ V}, V_{O(pp)} = 5 \text{ V}$ | | | 7.1 | | IVII I |
| SR | Slew rate | V _{CC} = ±15 V | | 80 ⁽¹⁾ 100 | | | V/µ |
| | Settling time to 0.1% | Gain = -1 | V _{CC} = ±15 V, 5-V step | | 60 | | ns |
| ٠. | Settling time to 0.176 | | V_{CC} = ±5 V, 2.5-V step | | 45 | | 115 |
| t _S | Settling time to 0.01% | Gain = -1 | V _{CC} = ±15 V, 5-V step | | 90 | | ns |
| | Settling time to 0.01% | | V _{CC} = ±5 V, 2.5-V step | | 80 | | 115 |
| NOISE/ | DISTORTION PERFORMANCE | | | | | • | |
| THD | Total harmonic distortion | $V_{CC} = \pm 5 \text{ V or } \pm 15 \text{ V,}$ f = 1 MHz, Gain = 2, $V_{O(pp)} = 2 \text{ V,}$ $T_A = 25^{\circ}\text{C}$ | $V_{CC} = \pm 5 \text{ V or } \pm 15 \text{ V,}$ f = 1 MHz, Gain = 2, $V_{O(pp)} = 2 \text{ V,}$ $T_A = 25^{\circ}\text{C}$ | | -96 | | dBo |
| DC PER | FORMANCE | | · | | | | |
| | | V _{CC} = ±15 V, V _O = ±10 V | T _A = 25°C | 93 | 98 | | |
| | Open loop gain | V _{CC} - ±15 V, V _O - ±10 V | T _A = full range | 92 | | | dB |
| | Орен юор даш | $V_{CC} = \pm 5 \text{ V}, V_{O} = \pm 2.5 \text{ V}$ | T _A = 25°C | 92 | 95 | | uL |
| | | V _{CC} - 13 v, v ₀ - 12.3 v | T _A = full range | 91 | | | |
| V _{OS} | Input offset voltage | V _{CC} = ±5 V or ±15 V | T _A = 25°C | | 0.5 | 2 | m۱ |
| VOS | input onset voltage | ACC - 72 A QL 7.12 A | T _A = full range | | | 3 | m\ |
| I | Input bias current | $V_{CC} = \pm 5 \text{ V or } \pm 15 \text{ V}$ | T _A = 25°C | | 3 | 6 | μA |
| I _{IB} | Input bias current | V _{CC} = ±3 V OF ±15 V | T _A = full range | | | 8 | μ |
| | Input offset current | V _{CC} = ±5 V or ±15 V | T _A = 25°C | | 30 | 250 | nΑ |
| los | mput onset outlett | ACC - TO A OL T LO A | T _A = full range | | | 400 | |
| | Input offset current drift | V _{CC} = ±5 V or ±15 V | T _A = full range | | 0.2 | | nA/° |
| | Offset voltage drift | V _{CC} = ±5 V or ±15 V | T _A = full range | | 2 | | μV/° |

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Keep junction temperature less than the absolute maximum rating when the output is heavily loaded or shorted; see also Section 5.1.

at T_A = full range, V_{CC} = ±15 V, and R_L = 1 k Ω (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|-----------------|--------------------------------------|---|-----------------------------|-------|-------|-------|------|
| INPUT C | HARACTERISTICS | | | | | | |
| | Common-mode input voltage | V _{CC} = ±15 V | V _{CC} = ±15 V | ±13.5 | ±14.3 | | V |
| V_{ICR} | range | V _{CC} = ±5 V | V _{CC} = ±5 V | ±3.8 | ±4.3 | | V |
| | | V - 145 V V - 140 V | T _A = 25°C | 85 | 95 | | |
| CMRR | Common-mode rejection ratio | $V_{CC} = \pm 15 \text{ V}, V_{ICR} = \pm 12 \text{ V}$ | T _A = full range | 80 | | | dB |
| CIVIRR | Common-mode rejection ratio | $V_{CC} = \pm 5 \text{ V}, V_{ICR} = \pm 2.5 \text{ V}$ | T _A = 25°C | 90 | 100 | | uБ |
| | | | T _A = full range | 85 | | | |
| rį | Input resistance | | | | 2 | | ΜΩ |
| Ci | Input capacitance | | | | 1.5 | | pF |
| OUTPUT | CHARACTERISTICS | - | | | | 1 | |
| | Outratually as and | V _{CC} = ±15 V | | ±13 | ±13.6 | | V |
| Vo | Output voltage swing | V _{CC} = ±5 V | | ±3.4 | ±3.8 | | V |
| | 0 1 1 (2) | R _L = 20 Ω | V _{CC} = ±15 V | 60 | 90 | | A |
| I ₀ | Output current ⁽²⁾ | | V _{CC} = ±5 V | 50 | 70 | | mA |
| I _{SC} | Short-circuit current ⁽³⁾ | V _{CC} = ±15 V | V _{CC} = ±15 V | | 150 | | mA |
| Ro | Output resistance | Open loop | <u>'</u> | | 13 | | Ω |
| POWER | SUPPLY | - | | | | 1 | |
| | 0 | Dual supply | | ±4.5 | | ±16.5 | V |
| V _{CC} | Supply voltage operating range | Single supply | | 9 | | 33 | V |
| | | V .45.V | T _A = 25°C | | 8.5 | 10 | |
| | | V _{CC} = ±15 V | T _A = full range | | | 11 | |
| Icc | Supply current (each amplifier) | .51/ | T _A = 25°C | | 7.5 | 9 | mA |
| | | $V_{CC} = \pm 5 \text{ V}$ | T _A = full range | | | 10 | |
| DODD | B 1 1 2 2 | V .5V .45V | T _A = 25°C | 85 | 95 | | |
| PSRR | Power-supply rejection ratio | ratio $V_{CC} = \pm 5 \text{ V or } \pm 15 \text{ V}$ | T _A = full range | 80 | | | dB |

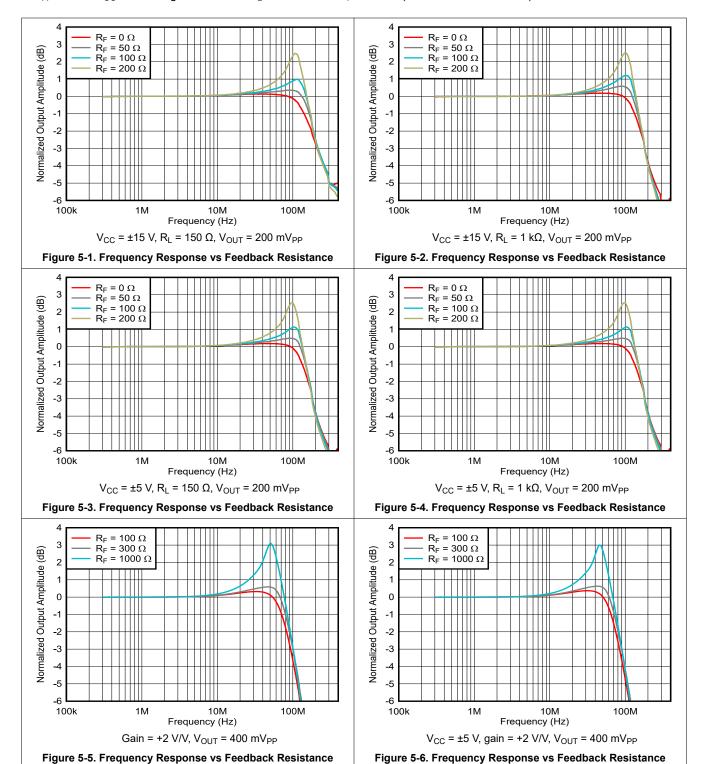
This parameter is not tested. (1)

⁽²⁾

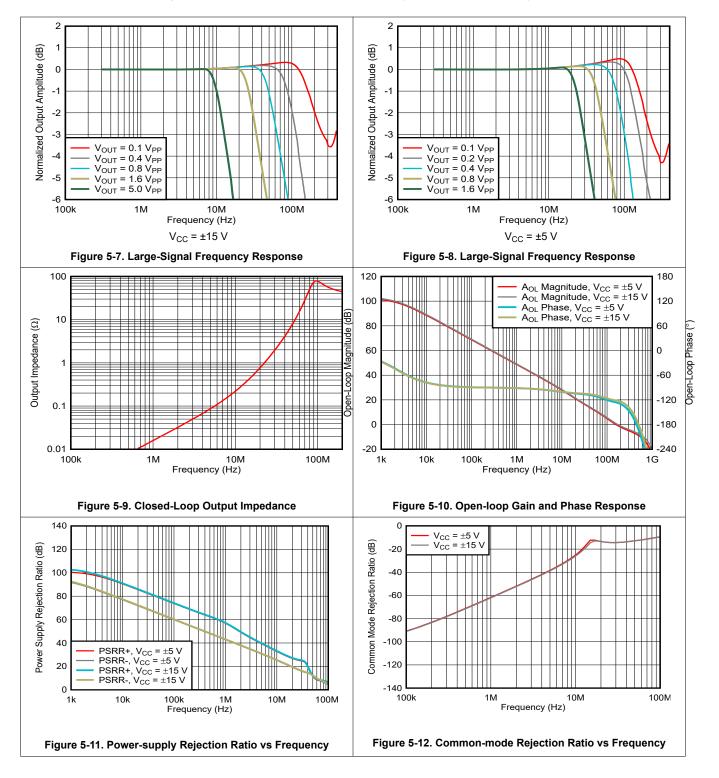
Full power bandwidth = slew rate / $[\sqrt{2} \text{ TV}_{OC(Peak)}]$. Keep junction temperature less than the absolute maximum rating when the output is heavily loaded or shorted; see also Section 5.1.



5.10 Typical Characteristics: THS4031

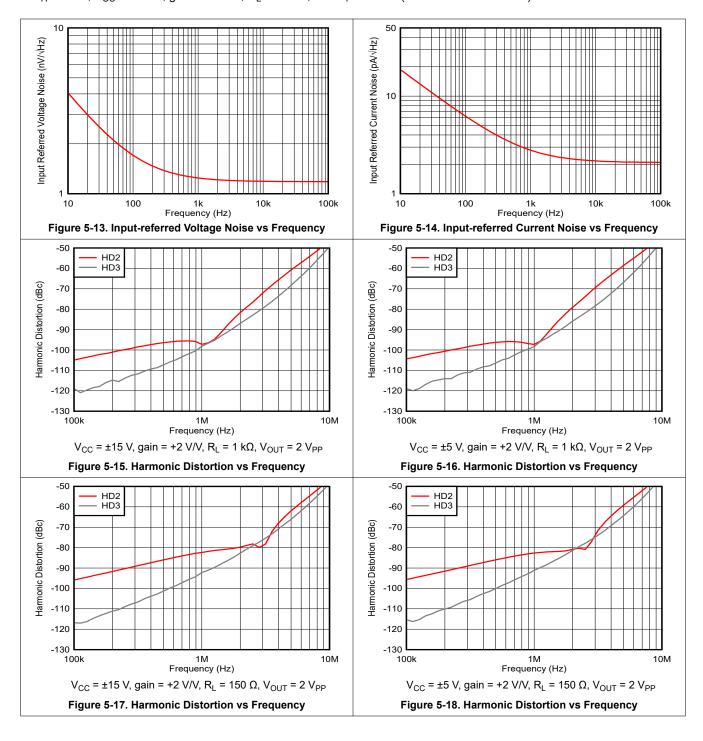






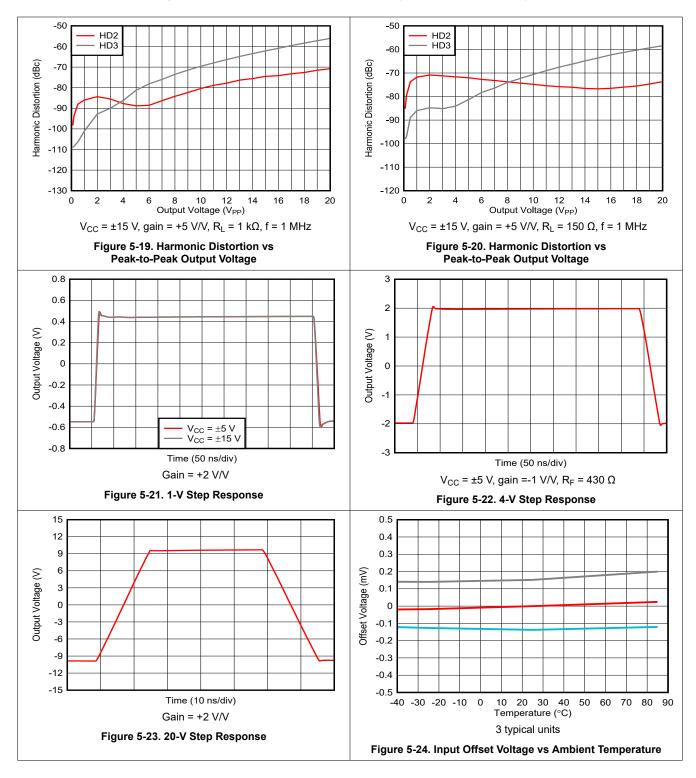


at T_A = 25°C, V_{CC} = ± 15 V, gain = +2 V/V, R_L = 150 Ω , and R_F = 300 Ω (unless otherwise noted)

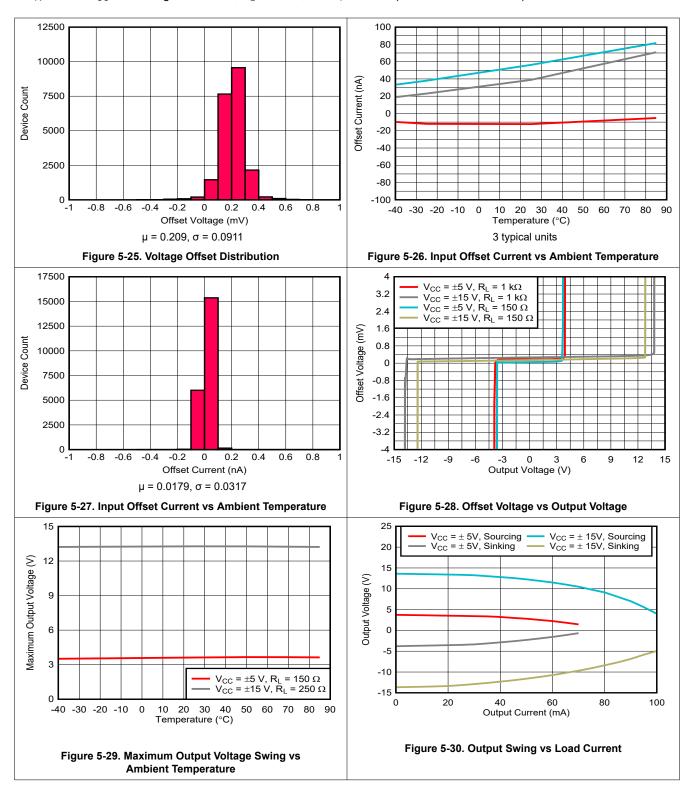


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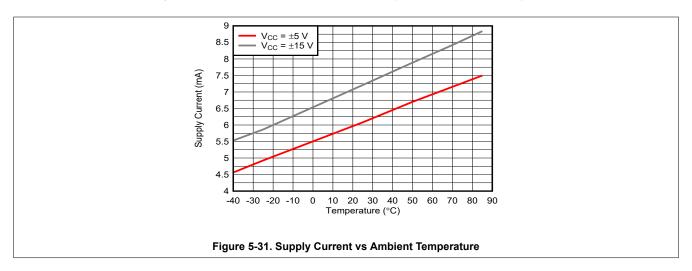






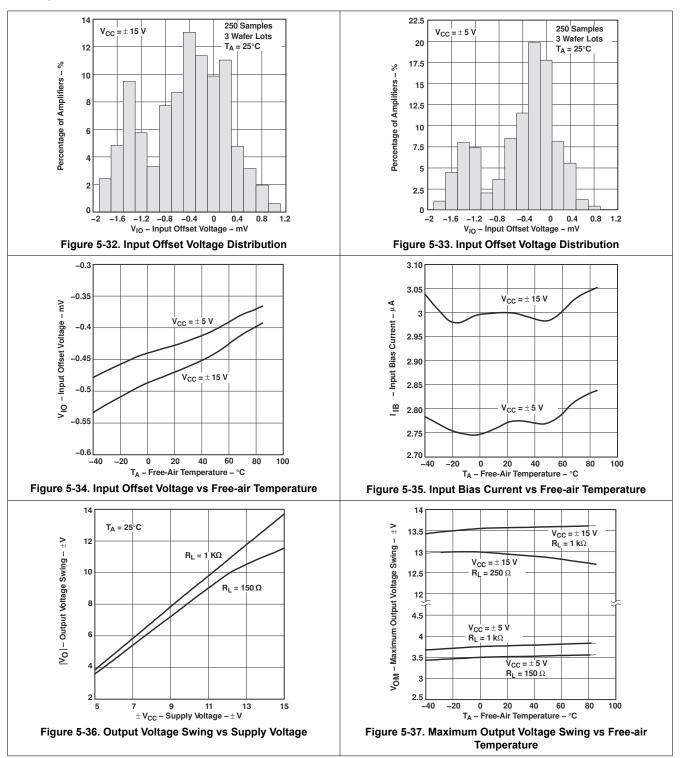








5.11 Typical Characteristics: THS4032





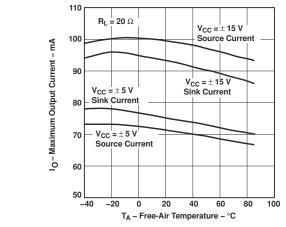


Figure 5-38. Maximum Output Current vs Free-air Temperature

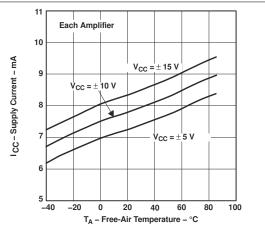


Figure 5-39. Supply Current vs Free-air Temperature

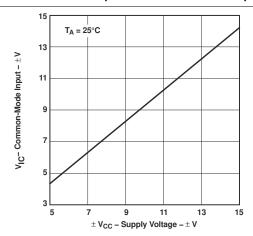


Figure 5-40. Common-mode Input Voltage vs Supply Voltage

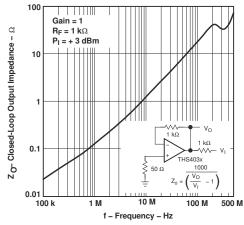
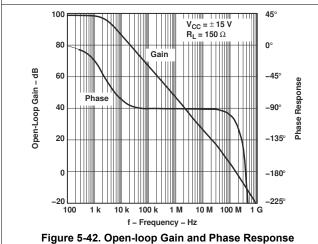


Figure 5-41. Closed-loop Output Impedance vs Frequency



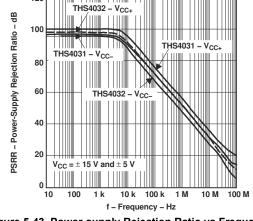
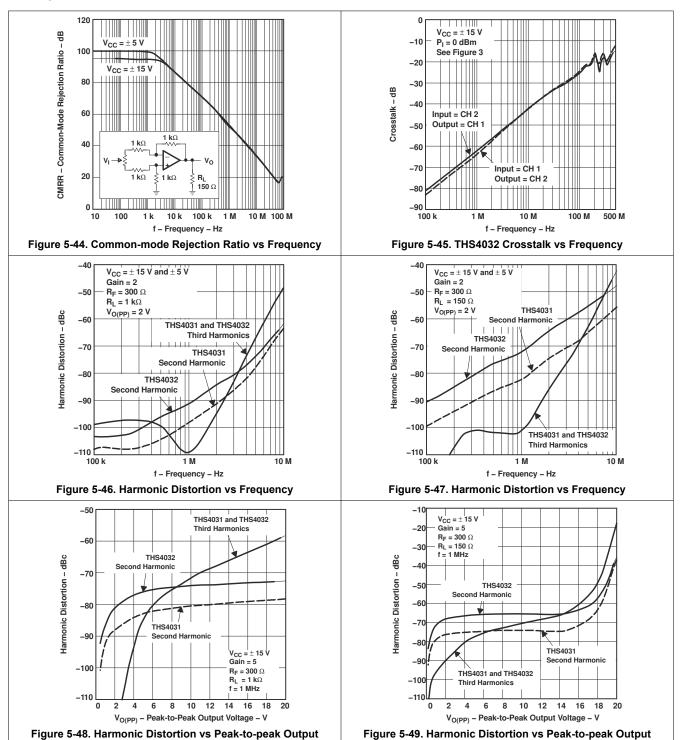


Figure 5-43. Power-supply Rejection Ratio vs Frequency



Voltage

Voltage



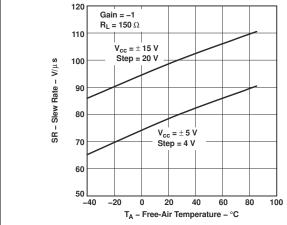


Figure 5-50. Slew Rate vs Free-air temperature

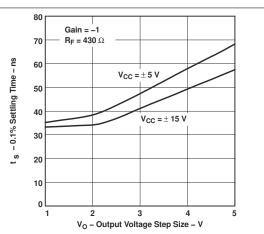


Figure 5-51. 0.1% Settling Time vs Output Voltage Step Size

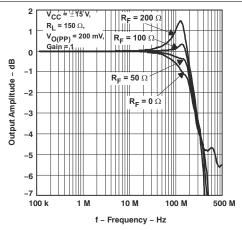


Figure 5-52. Small Signal Frequency Response With Varying Feedback Resistance

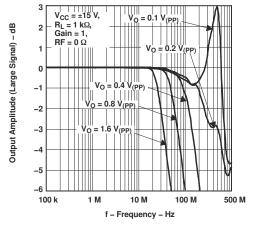


Figure 5-53. Frequency Response With Varying Output Voltage Swing

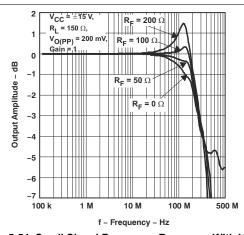


Figure 5-54. Small Signal Frequency Response With Varying Feedback Resistance

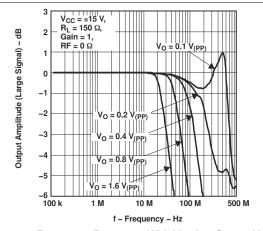


Figure 5-55. Frequency Response With Varying Output Voltage Swing



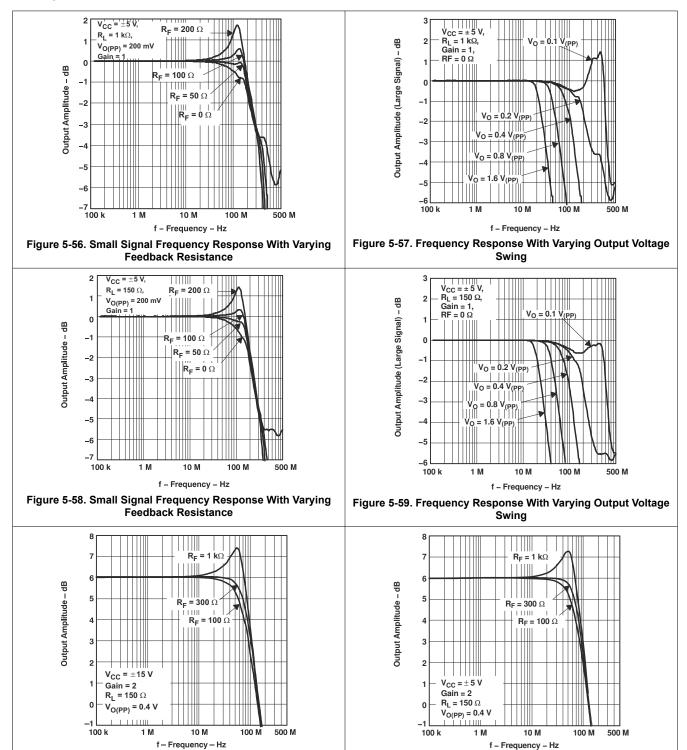


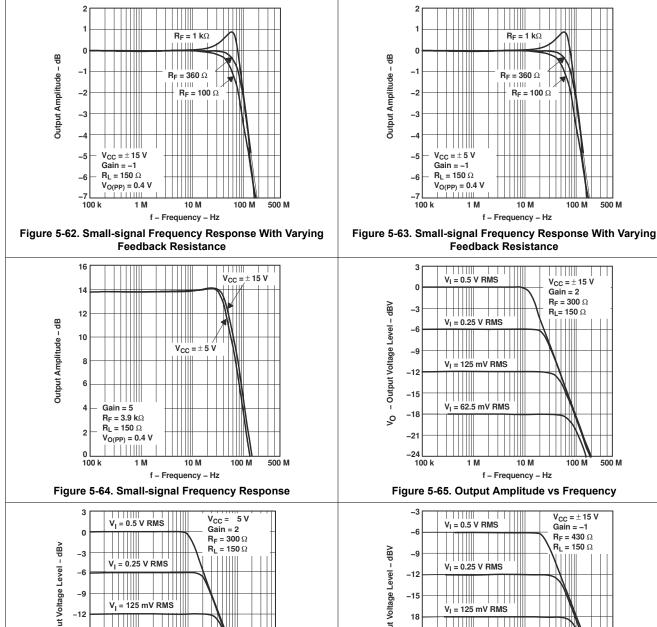
Figure 5-60. Small-signal Frequency Response With Varying

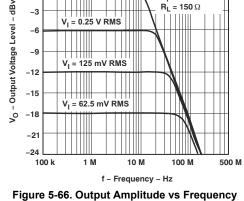
Feedback Resistance

Figure 5-61. Small-signal Frequency Response With Varying

Feedback Resistance







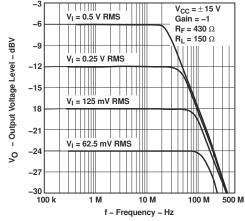
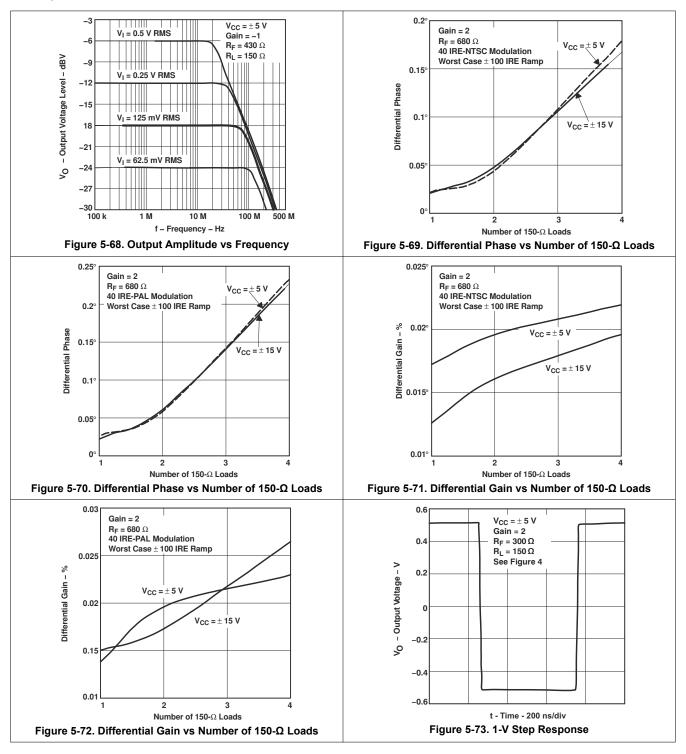


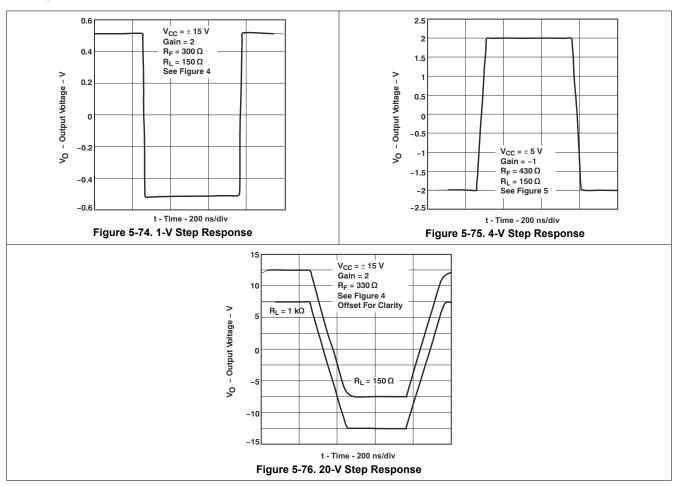
Figure 5-67. Output Amplitude vs Frequency





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6 Detailed Description

6.1 Overview

The THS403x is a high-speed operational amplifier configured in a voltage feedback architecture. These amplifiers is built using a 30-V, complementary bipolar process with NPN and PNP transistors that possess an f_T of several GHz. This configuration results in exceptionally high-performance amplifiers with wide bandwidth, high slew rate, fast settling time, and low distortion.

6.2 Functional Block Diagrams

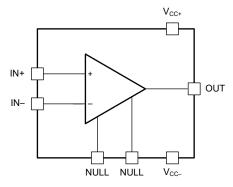


Figure 6-1. THS4031: Single Channel

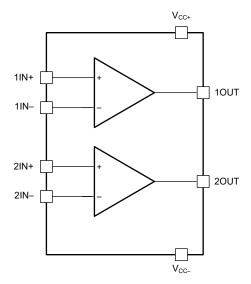


Figure 6-2. THS4032: Dual Channel

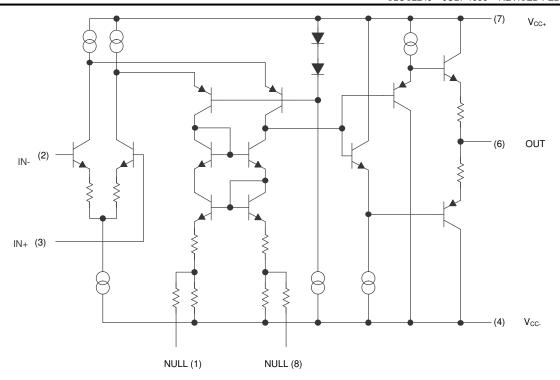


Figure 6-3. THS4031 Simplified Schematic

6.3 Feature Description

6.3.1 Offset Nulling

The THS403x have a very low input offset voltage for high-speed amplifiers. However, if additional correction is required, an offset nulling function has been provided on the THS4031. To adjust the input offset voltage, place a potentiometer between pin 1 and pin 8 of the device, and tie the wiper to the negative supply. Figure 6-4 shows this feature.

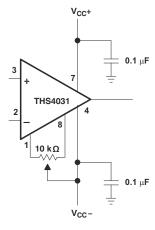


Figure 6-4. Offset Nulling Schematic

6.4 Device Functional Modes

The THS403x family has a single functional mode and can be used with both single-supply or split power-supply configurations. The power-supply voltage must be greater than $9 \text{ V} (\pm 4.5 \text{ V})$ and less than $33 \text{ V} (\pm 16.5 \text{ V})$.

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

7.1.1 Driving a Capacitive Load

The THS403x devices are internally compensated to maximize bandwidth and slew-rate performance. Take additional precautions when driving capacitive loads with a high-performance amplifier to maintain stability. As a result of the internal compensation, significant capacitive loading directly on the output node decreases the device phase margin, and potentially leads to high-frequency ringing or oscillations. Therefore, for capacitive loads greater than 10 pF, place an isolation resistor in series with the output of the amplifier. Figure 7-1 shows this configuration. For most applications, a minimum resistance of 20 Ω is recommended. In 75- Ω transmission systems, setting the series resistor value to 75 Ω is a beneficial choice because this value isolates any capacitance loading and provides source impedance matching.

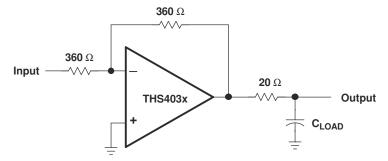


Figure 7-1. Driving a Capacitive Load

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7.1.2 Low-pass Filter Configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. Figure 7-2 shows how the simplest way to accomplish this limiting is to place an RC filter at the non-inverting pin of the amplifier.

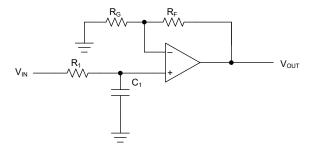


Figure 7-2. Single-pole Low-pass Filter

$$\frac{V_{OUT}}{V_{IN}} = \left(1 + \frac{R_F}{R_G}\right) \times \left(\frac{1}{1 + sR_1C_1}\right) \tag{1}$$

If more attenuation at higher frequencies is required, a multiple-pole filter is required. Figure 7-3 shows a common implementation of a second-order filter called a Sallen-Key filter. When designing this type of filter, chose an amplifier who bandwidth is approximately an order of magnitude larger than the desired filter bandwidth. See Active Low-pass Filter Design for more detailed active-filter design information.

Assuming $R_1 = R_2 = R$ and $C_1 = C_2 = C$, use Equation 2 to set the bandwidth of the filter.

$$f_{3dB} = \frac{1}{2\pi RC} \tag{2}$$

The Q-factor of a filter controls the amount of peaking of the small-signal frequency response and the settling time of the pulse response. Set Q to 0.707 to provide a Butterworth response with a maximally flat pass-band. Chose the ratio of R_F and R_G to obtain the desired Q value as shown in Equation 3.

$$\frac{R_F}{R_G} = 2 - \frac{1}{Q}$$

$$V_{IN} = \frac{R_1}{R_2}$$

$$V_{IN} = \frac{R_2}{R_2}$$

$$V_{OUT}$$

Figure 7-3. Two-pole Low-pass Sallen-Key Filter

7.2 Typical Application

This section demonstrates multiplexing several analog input signals to a high-performance driver amplifier which subsequently drives a single high-resolution, high-speed SAR analog-to-digital converter (ADC). This

example uses the ADS8411 and the TS5A3159 or TS5A3359 as the ADC and the multiplexer, respectively. This application uses the THS403x as the operational amplifier.

As detailed in Figure 7-4, the example system consists of an ADC (ADS8411), a driving operational amplifier (THS4031), a multiplexer (TS5A3159), an AC source, a DC source, and two driving operational amplifiers.

The driving amplifiers OPA1 are OPA2 are shown as two THS4031 amplifiers. Alternatively, use a single THS4032 to save on cost and board space. The purpose of these op-amps is make the input sources present a low impedance to rest of the circuit. Additionally, to maintain signal fidelity, these operational amplifiers must have low noise and distortion. The third THS4031 labeled OPA3 in Figure 7-4 is used to maintain switching speed and drive the ADC. The passive band-pass filter before the ADC reduces unwanted noise.

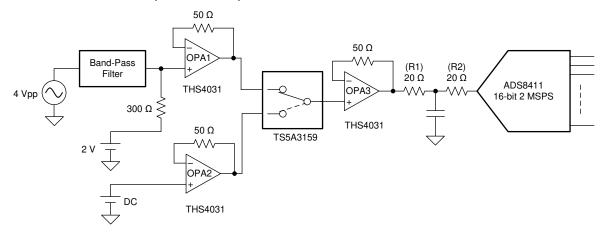


Figure 7-4. Multiplexing Set-up to Drive a High Performance ADC

7.2.1 Design Requirements

The objective to is design a multiplexed digitizer system with the dynamic performance shown in Table 7-1.

| DEVICE SPEED (MSPS) | INPUT FREQUENCY (kHz) | SNR (dB) | THD (dB) | CROSSTALK (dB) |
|------------------------|-----------------------|----------|----------|----------------|
| 2 | 20 | > 84 | < -90 | < -110 |
| 2 | 100 | > 84 | < -90 | < –96 |

Table 7-1. Design Specifications

7.2.2 Detailed Design Procedure

The ADS8411 is a 16-bit, 2-MSPS analog-to-digital converter (ADC) with a 4-V reference. The ADS8411 has a unipolar single-ended input and includes a 16-bit capacitor-based SAR ADC, with inherent sample and hold. The output is a 16-bit parallel interface.

The TS5A3159 is a single-pole, double-throw (SPDT) analog switch that is designed to operate from 1.65 V to 5.5 V. The TS5A3159 offers a low ON state resistance and an excellent ON resistance matching with the break-before-make feature to prevent signal distortion during the transfer of a signal from one channel to another. Additionally, the TS5A3159 provides excellent total harmonic distortion (THD) performance and consumes low power. The TS5A3359 is a single-pole, triple-throw (SP3T) version of the same switch.

7.2.2.1 Selection of Multiplexer

Figure 7-5 shows an equivalent circuit diagram of one of the channels of a multiplexer. C_S is the input capacitance of the channel; C_D is the output capacitance of the channel. R_{ON} is the resistance of the channel when the channel is turned ON. C_L and R_L are the load capacitance and resistance, respectively. V_{IN} is the input voltage of the source. R_S is the resistance of the source. V_{OUT} is the output voltage of the multiplexer.

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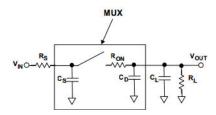


Figure 7-5. Multiplexer Equivalent Circuit

Settling time is improved when the values of R_S, R_{ON}, C_S, C_D, and C_L are small, and the value of R_L is large.

For TS5A3159:

- R_{ON} = 1 Ω
- $C_S = C_D = 84 pF$

Typical values for the extrinsic parameters are

- R_S = 50 Ω
- $C_L = 5 pF$
- $R_L = 10 \text{ k}\Omega$
- T_{RC} (time constant) = 8.65 ns

For a 16-bit system, at least 18-bit settling is desired to minimize distortion from settling artifacts. For an 18-bit settling, the circuit response time required is $(18 \times ln2) \times T_{RC} = 108$ ns, which is less than 2 MSPS sampling time of 500 ns. If the settling time is more than the conversion time of the ADC, the output of the multiplexer does not settle to the required accuracy resulting in distortion.

One more important parameter to consider when selecting a multiplexer is the on-state resistance variation with voltage. This variation also affects distortion because R_{ON} and R_{L} act like a resistor divider circuit. Any variation of R_{ON} with voltage affects the output voltage.

7.2.2.2 Signal Source

The input signal source must be a low-noise, low-distortion source with low source resistance. As discussed in the earlier section, the rouse resistance also must be small to avoid impacting settling time. If the source is not a low-noise and low-distortion source, a passive band-pass filter can be added to improve the signal quality as shown in Figure 7-4.

7.2.2.3 Driving Amplifier

The driving operational amplifier (OPA3 in Figure 7-4) in this application must have good slew rate, bandwidth, low noise, and distortion. The input of the operational amplifier can result in a maximum step of 4-V because of MUX switching. As a result, even if the signal bandwidth is low, the driving amplifier must settle from a 4-V step within one ADC sampling frame to avoid signal distortion. In this example, the settling requirement due to the ADC selection is 500 ns. The THS4031 is a good choice in this application due to the high slew rate and low distortion of this operational amplifier.

7.2.2.4 Driving Amplifier Bandwidth Restriction

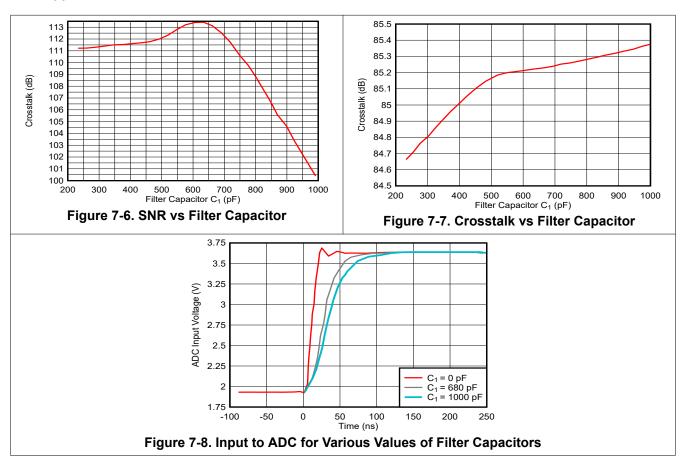
The restriction of excess bandwidth by use of a passive RC filter before the ADC results in better SNR and THD. However, restricting the bandwidth too much results in a excessive operational amplifier settling time. If the amplifier output does not settle quick enough, some residual charge of the previous channel remains in the next sampling interval and appears as crosstalk. One approach to solve this settling issue is to reduce the throughput of the ADC. However, often the high sample rate ADC was chosen to the need to acquire higher frequency signals limiting the freedom to reduce the ADC throughput. Due to these tradeoffs, the choice of the filter capacitor becomes critical. Figure 7-6 and Figure 7-7 show SNR and crosstalk as a function of the filter capacitor.



Figure 7-8 shows input settling behavior with three different filter capacitor values. The value of the capacitor changes to filter bandwidth. As the filter bandwidth increases, the settling time improves as shown in Equation 4.

Filter Bandwidth
$$\cong \frac{1}{2\pi R_1 C_1}$$
 (4)

7.2.3 Application Curves



7.3 Power Supply Recommendations

The THS403x family can operate off a single supply or with dual supplies. Choose supplies that provide for the required headroom to supply rails as specified by the common-mode input range (CMIR). Operating from a single supply can have numerous advantages. With the negative supply at ground, the DC errors due to the – PSRR term are minimized. Supplies must be decoupled with low inductance capacitors to ground as close to the amplifier as possible. When operating on a board with high-speed digital signals, make sure to provide isolation between digital signal noise and the analog input pins. When using a ground plane, removing the ground plane close to input sensitive pins reduces stray parasitics that adversely impact device performance. For split-supply operation, an optional supply decoupling capacitor across the two power supplies improves second harmonic distortion performance.

7.4 Layout

7.4.1 Layout Guidelines

To achieve the levels of high-frequency performance of the THS403x, follow proper printed-circuit board (PCB), high-frequency design techniques. The following is a general set of guidelines. In addition, a THS403x evaluation board is available to use as a guide for layout or for evaluating the device performance.

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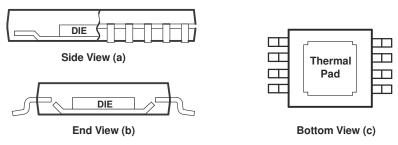
- Ground planes—make sure that the ground plane used on the board provides all components with a low-inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize stray capacitance.
- Proper power-supply decoupling—use a 6.8-µF tantalum capacitor in parallel with a 0.1-µF ceramic capacitor on each supply pin. Sharing the tantalum capacitor among several amplifiers is possible depending on the application, but always use a 0.1-µF ceramic capacitor on the supply pin of every amplifier. In addition, place the 0.1-µF capacitor as close as possible to the supply pin. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. Strive for distances of less than 0.1 inch (2.54 mm) between the device power pins and the ceramic capacitors.
- Short trace runs or compact part placements—optimum high-frequency performance is achieved when stray series inductance is minimized. To minimize stray inductance, make the circuit layout as compact as possible, thereby minimizing the length of all trace runs. Pay particular attention to the inputs of the amplifier, keeping the trace lengths as short as possible. This layout helps to minimize stray capacitance at the input of the amplifier.
- Sockets—TI does not recommend sockets for high-speed operational amplifiers. The additional lead inductance in the socket pins often leads to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- Short trace runs and compact part placements—Improved high-frequency performance is achieved when stray series inductance is minimized. To reduce stray series inductance, the circuit layout must be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention must be paid to the inverting input of the amplifier. The length must be kept as short as possible to minimize stray capacitance at the input of the amplifier.

7.4.1.1 General PowerPAD™ Design Considerations

The THS403x is available in a thermally-enhanced DGN package, which is a member of the PowerPAD™ family of packages. This package is constructed using a downset lead frame upon which the die is mounted [see Figure 7-9(a) and Figure 7-9(b)]. This arrangement results in the lead frame exposed as a thermal pad on the underside of the package [see Figure 7-9(c)]. Because this thermal pad has direct thermal contact with the die, excellent thermal performance can be achieved by providing a good thermal path away from the thermal pad.

The PowerPAD™ package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad can be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into a ground plane or other heat-dissipating device.

The PowerPAD™ integrated circuit package represents a breakthrough in combining the small area and ease of assembly of surface mount with the more-recent, awkward mechanical methods of heat sinking.



A. The thermal pad is electrically isolated from all pins in the package.

Figure 7-9. Views of Thermally-Enhanced DGN Package



Although there are many ways to properly heat sink this device, the following steps show the recommended approach.

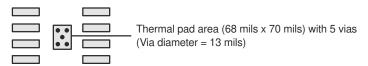


Figure 7-10. PowerPAD™ PCB Etch and Via Pattern

- 1. Prepare the PCB with a top-side etch pattern as shown in Figure 7-10. There must be etch for the leads as well as etch for the thermal pad.
- 2. Place five holes in the area of the thermal pad. These holes must be 13 mils (0.3302 mm) in diameter. The reason to keep the holes small is to discourage solder wicking through the holes during reflow.
- 3. Additional vias can be placed anywhere along the thermal plane outside of the thermal pad area. This action helps dissipate the heat generated by the THS403x device. The additional vias can be of any diameter because wicking is not a concern outside of the thermal pad area.
- 4. Connect all holes to the internal ground plane.
- 5. When connecting these holes to the ground plane, *do not* use the typical web or spoke via connection methodology. Web connections have a high thermal-resistance connection that is useful for slowing the heat transfer during soldering operations. This makes the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the THS403x package must connect to the internal ground plane with a complete connection around the entire circumference of the plated-through hole.
- 6. The top-side solder mask must leave the pins of the package and the thermal pad area with the five holes exposed. The bottom-side solder mask must cover the five holes of the thermal pad area, which prevents solder from pulling away from the thermal pad area during the reflow process.
- 7. Apply solder paste to the exposed thermal pad area and to all the device pins.
- 8. With these preparatory steps in place, the THS403x device is placed in position and run through the solder reflow operation as any standard surface-mount component. This results in a part that is properly installed.

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7.4.2 Layout Example

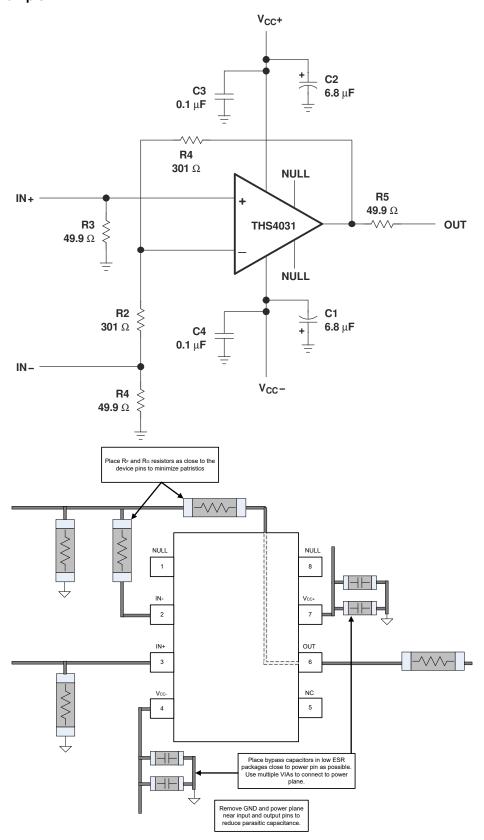


Figure 7-11. Layout Recommendations



8 Device and Documentation Support

8.1 Documentation Support

8.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, Noise Analysis for High-Speed Op Amps, application report
- Texas Instruments, *PowerPAD™ Thermally-Enhanced Package*, application report
- Texas Instruments, THS4031 High-Speed Op Amp, EVM user's guide
- Texas Instruments, THS4032 Dual High-Speed Op Amp, EVM user's guide

8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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8.4 Trademarks

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8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| С | hanges from Revision I (May 2018) to Revision J (February 2024) | Page |
|---|--|----------------|
| • | Updated the numbering format for tables, figures, and cross-references throughout the document | 1 |
| • | Changed table note 1 in Absolute Maximum Ratings to add additional clarification | 4 |
| • | Changed output current max in Absolute Maximum Ratings from 150 mA to 240 mA | 4 |
| • | Changed differential supply voltage in Absolute Maximum Ratings from ± 4 V to ± 1.5 V | 4 |
| • | Added continuous input current in Absolute Maximum Ratings | 4 |
| • | Deleted M-suffix temperature range and in Absolute Maximum Ratings | 4 |
| • | Deleted JG and FK package references in Absolute Maximum Ratings | 4 |
| • | Changed charged-device model (CDM) reference from JESD22-C101 to JS-002 in ESD Ratings | 4 |
| • | Updated Thermal Information: THS4031 for the D and DGN packages | |
| • | Deleted full-power bandwidth specification from <i>Electrical Characteristics: THS4031, R</i> _I = 150 Ω | 6 |
| • | Added Electrical Characteristics: THS4031, RL = 150 Ω section | <mark>6</mark> |
| • | Changed bandwidth for 0.1-dB flatness in <i>Electrical Characteristics: THS4031, R_I</i> = 150 Ω from 50 MH | |
| | MHz for $V_{CC} = \pm 15 \text{ V}$ | |

Product Folder Links: THS4031 THS4032



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| • | Changed bandwidth for 0.1-dB flatness in <i>Electrical Characteristics: THS4031, R_L</i> = 150 Ω from 45 MHz to 9 MHz for V _{CC} = ±5 V6 |
|---|--|
| • | Changed settling time to 0.1% in <i>Electrical Characteristics: THS4031, R_L</i> = 150 Ω from 60 ns to 70 ns for V _{CC} |
| | = ±15 V6 |
| • | Changed settling time to 0.1% in <i>Electrical Characteristics: THS4031</i> , R_L = 150 Ω from 45 ns to 55 ns for V_{CC} = ±5 V_{CC} |
| • | Deleted total harmonic distortion for 1 k Ω in <i>Electrical Characteristics THS4031</i> , R_I = 150 Ω |
| • | Changed input voltage noise - in <i>Electrical Characteristics: THS4031, R_L</i> = 150 Ω from 1.6 nV/ \sqrt{Hz} to 1.2 nV/ \sqrt{Hz} 6 |
| • | Changed input current noise in <i>Electrical Characteristics: THS4031, R_L</i> = 150 Ω from 1.2 pA/ \sqrt{Hz} to 2.3 |
| | pA√Hz |
| • | Changed open loop gain condition in <i>Electrical Characteristics THS4031</i> , R_L = 150 Ω from 1 k Ω to 150 Ω 6 Changed open loop gain minimum in <i>Electrical Characteristics THS4031</i> , R_L = 150 Ω from 98 dB to 100 dB |
| | for $V_{CC} = \pm 15 \text{ V}$, $T_A = 25 \text{ °C}$ 6 |
| • | Changed open loop gain minimum specification in <i>Electrical Characteristics THS4031</i> , R_L = 150 Ω from 95 dB to 98 dB for VCC = ±5 V, TA = 25 °C6 |
| • | Updated input offset voltage values and units specification in <i>Electrical Characteristics THS4031</i> , R_L = 150 Ω |
| • | Added input offset current specification in <i>Electrical Characteristics THS4031</i> , R_L = 150 Ω table |
| • | Changed common-mode input voltage range typical in <i>Electrical Characteristics THS4031,R</i> _L = 150 Ω from ±14 V to ±14.3 V for V _{CC} = ±15 V6 |
| | Changed common-mode input voltage range typical in <i>Electrical Characteristics THS4031</i> , R_L = 150 Ω from |
| | ±4 V to ±4.3 V for V _{CC} = ±5 V |
| • | Deleted output voltage swing for $R_1 = 1 \text{ k}\Omega$ in <i>Electrical Characteristics THS4031</i> , $R_1 = 150 \Omega$ 6 |
| • | Changed output voltage swing condition for V_{CC} = ±15 V in <i>Electrical Characteristics THS4031</i> , R_L = 150 Ω from 150 Ω to 250 Ω |
| • | Changed output voltage swing condition for V_{CC} = ±5 V in <i>Electrical Characteristics THS4031</i> , R_L = 150 Ω |
| | from 250 Ω to 150 Ω |
| • | Deleted short circuit current in <i>Electrical Characteristics: THS4031, R_L</i> = 150 Ω |
| • | Changed output current load resistance typical in <i>Electrical Characteristics THS4031</i> , R_L = 150 Ω from 20 Ω |
| | to 10 Ω |
| • | Changed output current typical in <i>Electrical Characteristics THS4031</i> , R_L = 150 Ω from 90 mA to 200 mA for V_{CC} = ±15V6 |
| • | Changed output current typical in <i>Electrical Characteristics THS4031</i> , R_L = 150 Ω from 70 mA to 160 mA for |
| | $V_{CC} = \pm 5V$ |
| • | Changed output resistance typical in <i>Electrical Characteristics THS4031</i> , R_L = 150 Ω from 13 Ω to 5 Ω 6 |
| • | Changed supply current (each amplifier) typical in <i>Electrical Characteristics THS4031</i> , R_L = 150 Ω from 8.5 |
| | mA to 7.5 mA for $V_{CC} = \pm 15 \text{ V}$ |
| • | Changed supply current (each amplifier) typical in <i>Electrical Characteristics THS4031</i> , $R_L = 150 \Omega$ from 7.5 |
| | mA to 6.5 mA for $V_{CC} = \pm 5 \text{ V}$ |
| • | Changed bandwidth for 0.1-dB flatness in <i>Electrical Characteristics: THS4031</i> , R_L = 1 $k\Omega$ from 50 MHz to 9 MHz for V_{CC} = ±15 $V_{$ |
| • | Changed bandwidth for 0.1-dB flatness in <i>Electrical Characteristics: THS4031, R_L</i> = 1 $k\Omega$ from 45 MHz to 9 |
| | MHz for V _{CC} = ±5 V8 |
| • | Changed full power bandwidth calculation from slew rate / $[\sqrt{\pi}V_{OC(Peak)}]$ to slew rate / $[\pi V_{O(P-P)}]$ in <i>Electrical Characteristics THS4031</i> , R_L = 1 $k\Omega$ |
| • | Changed full power bandwidth in <i>Electrical Characteristics: THS4031, R_L</i> = 1 $k\Omega$ from 2.3 to 1.6 for V _{CC} = |
| | ±15 V |
| • | Changed full power bandwidth specification in <i>Electrical Characteristics: THS4031, R_L</i> = 1 $k\Omega$ from 7.1 to 5.1 for V_{CC} = ±5 V_{CC} |
| • | Changed 0.1% setting time in <i>Electrical Characteristics: THS4031</i> , R_L = 1 $k\Omega$ from 60 to 70 for V_{CC} = ±15 V.8 |
| • | Changed 0.1% setting time in <i>Electrical Characteristics: THS4031, R_L</i> = 1 $k\Omega$ from 45 to 55 for V _{CC} = ±15 V 8 |



| <u> </u> | Deleted the graphs in the General PowerPAD™ Design Considerations section | 35 |
|----------|---|---------------------|
| • | Documentation Support section, and Mechanical, Packaging, and Orderable Information section Delete obsolete JG and FK packages | . 1 |
| - | Implementation section, Power Supply Recommendations section, Layout section, Device and | _ |
| <u>C</u> | hanges from Revision G (March 2010) to Revision H (March 2016) Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and | ge |
| | , | _ |
| • | Deleted Available Options table (POA information) | _ |
| C | hanges from Revision H (March 2016) to Revision I (May 2018) | ae |
| _ | Deleted thermal calculations in General FowerFAD integrated Circuit Fackage Design Considerations | |
| • | Changed name of General Configuration section to Low-pass Filter Configurations | |
| • | Changed Application Information section to latest standard format | |
| • | Deleted Noise Calculation and Noise Figure, Optimizing Frequency Response, and Offset Voltage sections 2 | |
| • | Deleted Parameter Measurement Information section. | |
| • | Changed title of Typical Characteristics to Typical Characteristics: THS4032 | |
| • | Added Typical Characteristics: THS4031 section | |
| | kΩ table | 12 |
| • | Deleted output voltage swing for RL = 150 Ω and RL = 250 Ω in Electrical Characteristics THS4032, RL = | |
| | specifications from <i>Electrical Characteristics: THS4032, R_L</i> = $1 k\Omega$ | 12 |
| • | Deleted 150 Ω input voltage noise, input current noise, differential gain error, and differential phase error, | 12 |
| | Changed title of Electrical Characteristics: $R_L = 1 \text{ k}\Omega$ to Electrical Characteristics: THS4032 $R_L = 1 \text{ k}\Omega$ | |
| | Deleted 1 k Ω open loop gain specification from in <i>Electrical Characteristics THS4032</i> , R_L = 150 Ω | |
| • | Changed title of <i>Electrical Characteristics</i> : R_L = 150 Ω to <i>Electrical Characteristics</i> : <i>THS4032</i> , R_L = 150 Ω Updated input offset voltage units specification in <i>Electrical Characteristics THS4032</i> , R_L = 150 Ω | |
| • | Deleted full-power bandwidth specification from <i>Electrical Characteristics: THS4032, R_L</i> = 150 Ω | |
| | mA for V _{CC} = ±5 V | |
| • | Changed supply current (each amplifier) in <i>Electrical Characteristics THS4031</i> , $R_L = 1 k\Omega$ from 7.5 mA to 6. | 5 |
| | to 7.5 mA for $V_{CC} = \pm 15 \text{ V}$ | |
| • | Changed supply current (each amplifier) typical in <i>Electrical Characteristics THS4031</i> , R_L = 1 $k\Omega$ from 8.5 m | |
| • | Deleted output resistance in <i>Electrical Characteristics: THS4031, R</i> _L =1 $k\Omega$ | |
| • | Deleted output current in <i>Electrical Characteristics THS4031</i> , $R_L = 1 k\Omega$ table | |
| | $k\Omega$ table | . 8 |
| • | Deleted output voltage swing for R_L = 150 Ω and R_L = 250 Ω in <i>Electrical Characteristics THS4031</i> , R_L = | |
| | = full range | 8 |
| | = 25°C Changed input bias current max in <i>Electrical Characteristics THS4031, R_L</i> = 1 $k\Omega$ from 8 μ A to 33 μ A for T _A | |
| • | Changed input bias current max in <i>Electrical Characteristics THS4031</i> , $R_L = 1 k\Omega$ from 6 μ A to 20 μ A for T_A | |
| • | Changed input bias current typical in <i>Electrical Characteristics THS4031</i> , R_L = 1 $k\Omega$ from 3 μ A to 9 μ A for T = 25°C | А <mark>8</mark> |
| | 0.3 mV | |
| • | Changed input offset voltage typical in <i>Electrical Characteristics THS4031</i> , $R_L = 1k \Omega$ from 0.5 mV to | |
| • | V_{CC} = ±5 V, T_A = 25 °C | |
| _ | VCC = ±15 V, T_A = 25 °C Changed open loop gain minimum in <i>Electrical Characteristics THS4031</i> , R_L = 1 $k\Omega$ from 95 dB to 98 dB for | . 8 |
| • | Changed open loop gain minimum in <i>Electrical Characteristics THS4031</i> , $R_L = 1 \text{ k}\Omega$ from 98 dB to 100 dB f | |
| | error for R _L = 150 Ω in <i>Electrical Characteristics THS4031</i> , R_L = 1 $k\Omega$ | |
| • | Deleted total harmonic distortion, voltage noise, current noise, differential gain error, and differential phase | |

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| 4 | INSTRUMENTS |
|-------|-------------|
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| | |

| Changes from Revision F (September 2008) to Revision G (March 2010) | Page |
|---|--------------|
| • Changed units for input voltage noise parameter (full range of T _A specifications) from nA/√ | Hz to nV√Hz4 |
| Changes from Revision E (June 2007) to Revision F (September 2008) | Page |
| Deleted bullet point for Stable in Gain of 2 (-1) or greater | 1 |
| Editorial changes to paragraph format | 34 |

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan | Lead finish/ Ball material | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|------------|--------------|--------------------|------|----------------|--------------|-------------------------------|--------------------|--------------|----------------------|---------|
| THS4031CD | LIFEBUY | SOIC | D | 8 | 75 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 4031C | |
| THS4031CDGN | LIFEBUY | HVSSOP | DGN | 8 | 80 | RoHS & Green | NIPDAU NIPDAUAG | Level-1-260C-UNLIM | 0 to 70 | ACM | |
| THS4031CDGNR | LIFEBUY | HVSSOP | DGN | 8 | 2500 | RoHS & Green | NIPDAU NIPDAUAG | Level-1-260C-UNLIM | 0 to 70 | ACM | |
| THS4031ID | LIFEBUY | SOIC | D | 8 | 75 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 40311 | |
| THS4031IDG4 | LIFEBUY | SOIC | D | 8 | 75 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 40311 | |
| THS4031IDGN | LIFEBUY | HVSSOP | DGN | 8 | 80 | RoHS & Green | NIPDAU NIPDAUAG | Level-1-260C-UNLIM | -40 to 85 | ACN | |
| THS4031IDGNG4 | LIFEBUY | HVSSOP | DGN | 8 | 80 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | ACN | |
| THS4031IDGNR | ACTIVE | HVSSOP | DGN | 8 | 2500 | RoHS & Green | NIPDAU NIPDAUAG | Level-1-260C-UNLIM | -40 to 85 | ACN | Samples |
| THS4031IDR | ACTIVE | SOIC | D | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 40311 | Samples |
| THS4032ID | LIFEBUY | SOIC | D | 8 | 75 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 40321 | |
| THS4032IDG4 | LIFEBUY | SOIC | D | 8 | 75 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 40321 | |
| THS4032IDGNR | ACTIVE | HVSSOP | DGN | 8 | 2500 | RoHS & Green | NIPDAU NIPDAUAG | Level-1-260C-UNLIM | -40 to 85 | ABG | Samples |
| THS4032IDR | ACTIVE | SOIC | D | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | 40321 | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

PACKAGE OPTION ADDENDUM

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(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF THS4031, THS4032:

● Enhanced Product : THS4032-EP

Military: THS4031M

NOTE: Qualified Version Definitions:

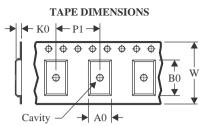
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| THS4031CDGNR | HVSSOP | DGN | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| THS4031IDGNR | HVSSOP | DGN | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| THS4031IDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| THS4032IDGNR | HVSSOP | DGN | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| THS4032IDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |



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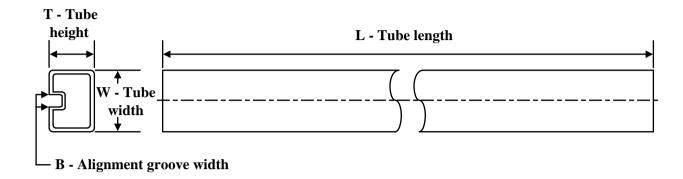
*All dimensions are nominal

| 7 till dillitorioriorio di o mominar | | | | | | | |
|--------------------------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
| THS4031CDGNR | HVSSOP | DGN | 8 | 2500 | 364.0 | 364.0 | 27.0 |
| THS4031IDGNR | HVSSOP | DGN | 8 | 2500 | 364.0 | 364.0 | 27.0 |
| THS4031IDR | SOIC | D | 8 | 2500 | 350.0 | 350.0 | 43.0 |
| THS4032IDGNR | HVSSOP | DGN | 8 | 2500 | 364.0 | 364.0 | 27.0 |
| THS4032IDR | SOIC | D | 8 | 2500 | 350.0 | 350.0 | 43.0 |

PACKAGE MATERIALS INFORMATION

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TUBE



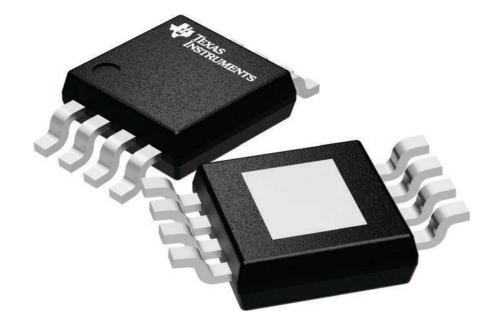
*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (µm) | B (mm) |
|---------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| THS4031CD | D | SOIC | 8 | 75 | 505.46 | 6.76 | 3810 | 4 |
| THS4031CDGN | DGN | HVSSOP | 8 | 80 | 330 | 6.55 | 500 | 2.88 |
| THS4031ID | D | SOIC | 8 | 75 | 505.46 | 6.76 | 3810 | 4 |
| THS4031IDG4 | D | SOIC | 8 | 75 | 505.46 | 6.76 | 3810 | 4 |
| THS4031IDGN | DGN | HVSSOP | 8 | 80 | 330 | 6.55 | 500 | 2.88 |
| THS4031IDGNG4 | DGN | HVSSOP | 8 | 80 | 330 | 6.55 | 500 | 2.88 |
| THS4032ID | D | SOIC | 8 | 75 | 505.46 | 6.76 | 3810 | 4 |
| THS4032IDG4 | D | SOIC | 8 | 75 | 505.46 | 6.76 | 3810 | 4 |

3 x 3, 0.65 mm pitch

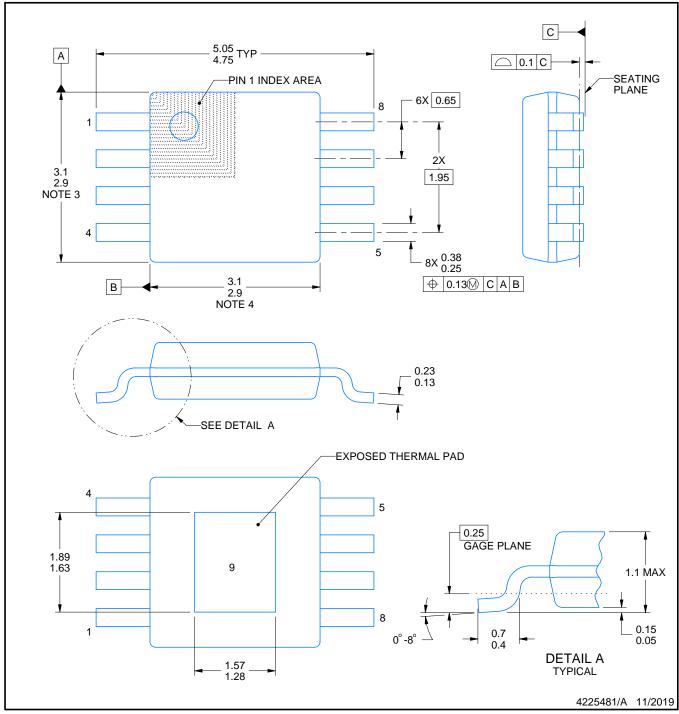
SMALL OUTLINE PACKAGE

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



$\textbf{PowerPAD}^{^{\text{\tiny{TM}}}}\,\textbf{VSSOP - 1.1 mm max height}$

SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

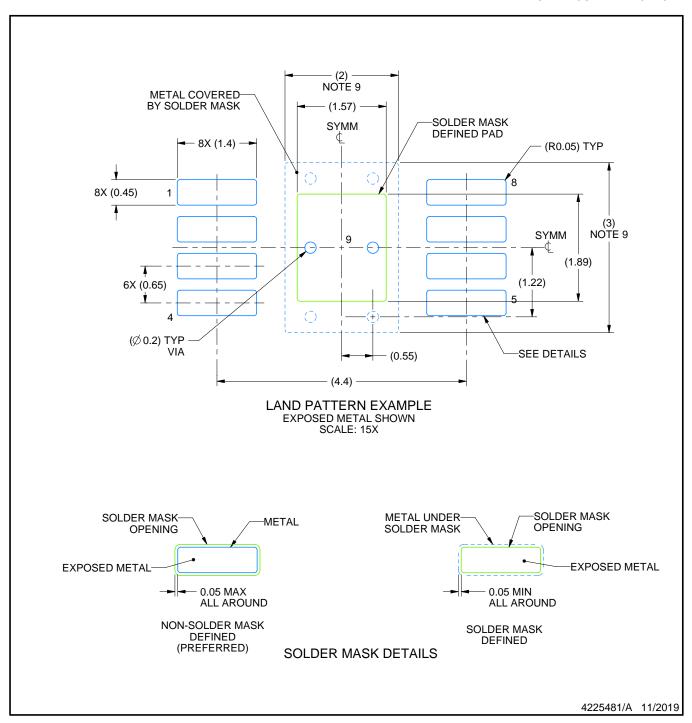
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



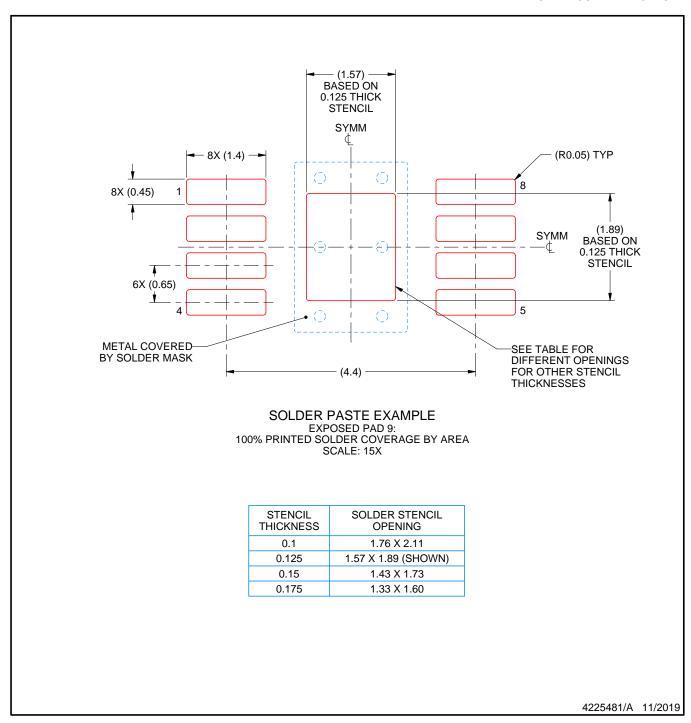
SMALL OUTLINE PACKAGE



- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.



SMALL OUTLINE PACKAGE

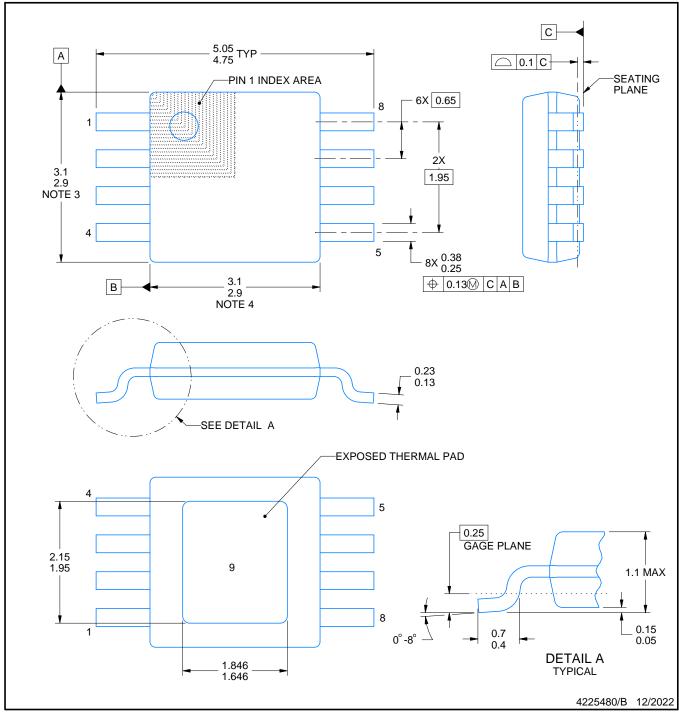


- 10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 11. Board assembly site may have different recommendations for stencil design.



$\textbf{PowerPAD}^{^{\text{\tiny{TM}}}}\,\textbf{VSSOP - 1.1 mm max height}$

SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

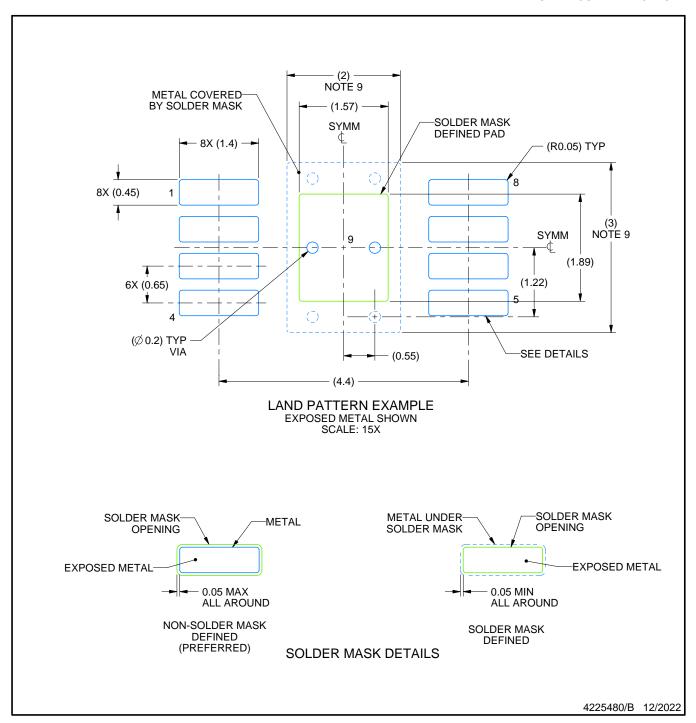
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



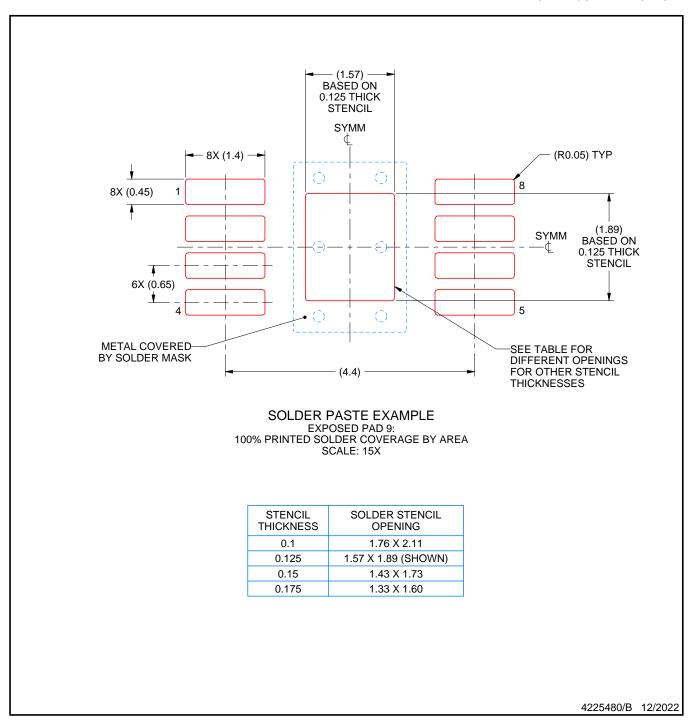
SMALL OUTLINE PACKAGE



- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.



SMALL OUTLINE PACKAGE



- 10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 11. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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